

DS280BR810 低功耗 28Gbps 8 通道线性中继器

1 特性

- 八通道多协议线性均衡器，可支持传输速率高达 28Gbps 的接口
- 低功耗：93mW 和通道（典型值）
- 无需散热器
- 无缝支持 CR4/KR4 链路协商的线性均衡器
- 扩展通道长度，超出正常专用集成电路 (ASIC) 到 ASIC 性能 15dB+
- 超低延迟：100ps（典型值）
- 低附加随机抖动
- 采用集成 RX 和 TX 交流耦合电容的 8mm x 13mm BGA 小封装，适用于简易直通布线
- 独特的引脚分配支持在封装下对高速信号进行路由
- 提供引脚兼容的重定时器
- 2.5V±5% 单电源
- 运行温度范围：-40°C 至 +85°C

2 应用

- [背板和中板长度延长](#)
- 用于光纤铜缆和无源铜缆 (100G-SR4/LR4/CR4) 的前端口眼图开启器
- QSFP28、SFP28、CFP2、CFP4、CDFP

3 说明

DS280BR810 是一款超低功耗、高性能八通道线性均衡器，支持数据传输速率高达 28Gbps 的多速率、多协议接口。该器件可用于扩展长度范围并提高前端口、背板和芯片至芯片应用的高速串行链路的稳定性。

DS280BR810 均衡器的线性特质保留了发射信号的特性，因此允许主机与链路合作伙伴 ASIC 自由协商发射均衡器系数 (100G-CR4/KR4)。这种链路协商协议的透明管理有助于在对延迟影响最小的情况下实现系统级互操作性。每个通道独立运行，允许 DS280BR810 进行独立信道前向纠错 (FEC)。

DS280BR810 将小型封装尺寸、经优化的高速信号退出和引脚兼容的重定时器相结合，使其成为高密度背板的理想应用。凭借简化的均衡控制、低功耗和超低附加抖动特性，该器件适用于 100G-SR4/LR4/CR4 等前端接口。8mm x 13mm 小型封装（如 QSFP28、SFP28、CFP2/CFP4 和 CDFP）适用于多种标准前端接口连接器，并且无需散热器。

集成 AC 耦合电容 (RX 与 TX) 免除了集成电路板 (PCB) 对于外部电容的需求。DS280BR810 具备一个单电源，能够最大限度地降低外部组件的数量。这些特性降低了 PCB 布局布线复杂度以及物料清单 (BOM) 成本。

引脚兼容的重定时器可用于距离较长的应用。

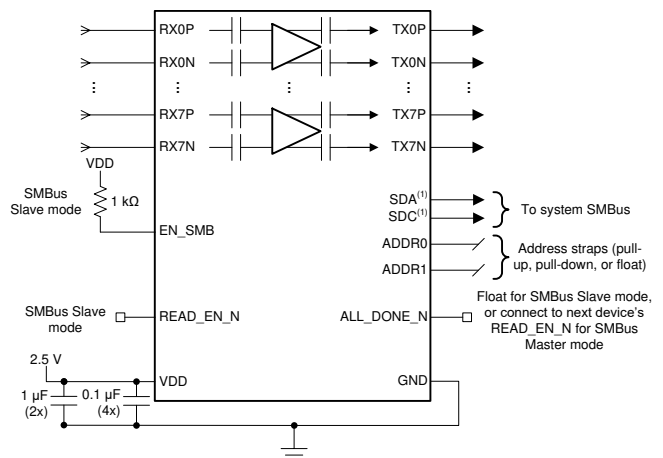
DS280BR810 可通过 SMBus 或外部 EEPROM 进行配置。单个 EEPROM 最多可由 16 个器件共享。

器件信息 (1)

| 器件型号 | 封装 | 封装尺寸（标称值） |
|------------|-------------|------------------|
| DS280BR810 | nFBGA (135) | 8.00mm x 13.00mm |

(1) 想了解所有可用封装，请参见数据表末尾的可订购产品附录。

简化电路原理图



(1) SMBus signals need to be pulled up elsewhere in the system.

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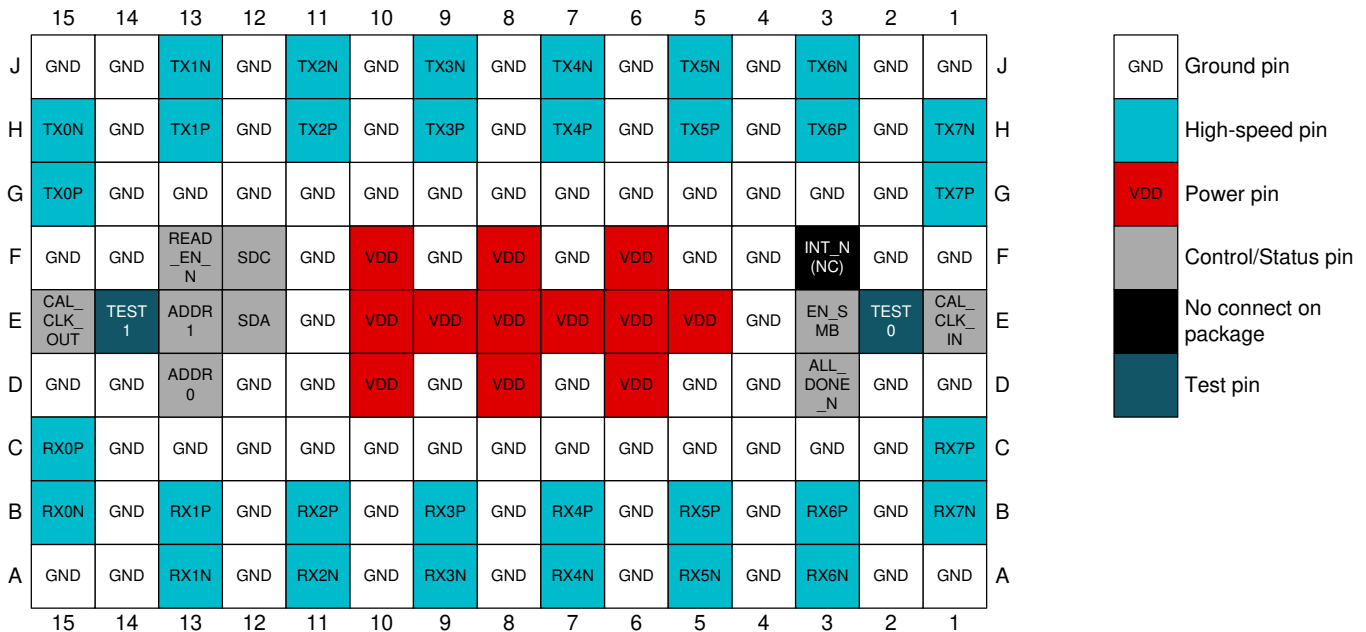
4 修订历史记录

注：之前版本的页码可能与当前版本有所不同。

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5 Pin Configuration and Functions

ZBF Package
135-Pin nfBGA
Top View



Pin Functions

| PIN | | I/O | DESCRIPTION |
|-----------------------------|-----|--------|---|
| NAME | NO. | | |
| HIGH SPEED DIFFERENTIAL I/O | | | |
| RX0N | B15 | Input | Inverting and non-inverting differential inputs to the equalizer. An on-chip 100-Ω termination resistor connects RXP to RXN. These inputs are AC coupled with 220-nF capacitors assembled on the package substrate. |
| RX0P | C15 | Input | |
| RX1N | A13 | Input | Inverting and non-inverting differential inputs to the equalizer. An on-chip 100-Ω termination resistor connects RXP to RXN. These inputs are AC coupled with 220-nF capacitors assembled on the package substrate. |
| RX1P | B13 | Input | |
| RX2N | A11 | Input | Inverting and non-inverting differential inputs to the equalizer. An on-chip 100-Ω termination resistor connects RXP to RXN. These inputs are AC coupled with 220-nF capacitors assembled on the package substrate. |
| RX2P | B11 | Input | |
| RX3N | A9 | Input | Inverting and non-inverting differential inputs to the equalizer. An on-chip 100-Ω termination resistor connects RXP to RXN. These inputs are AC coupled with 220-nF capacitors assembled on the package substrate. |
| RX3P | B9 | Input | |
| RX4N | A7 | Input | Inverting and non-inverting differential inputs to the equalizer. An on-chip 100-Ω termination resistor connects RXP to RXN. These inputs are AC coupled with 220-nF capacitors assembled on the package substrate. |
| RX4P | B7 | Input | |
| RX5N | A5 | Input | Inverting and non-inverting differential inputs to the equalizer. An on-chip 100-Ω termination resistor connects RXP to RXN. These inputs are AC coupled with 220-nF capacitors assembled on the package substrate. |
| RX5P | B5 | Input | |
| RX6N | A3 | Input | Inverting and non-inverting differential inputs to the equalizer. An on-chip 100-Ω termination resistor connects RXP to RXN. These inputs are AC coupled with 220-nF capacitors assembled on the package substrate. |
| RX6P | B3 | Input | |
| RX7N | B1 | Input | Inverting and non-inverting differential inputs to the equalizer. An on-chip 100-Ω termination resistor connects RXP to RXN. These inputs are AC coupled with 220-nF capacitors assembled on the package substrate. |
| RX7P | C1 | Input | |
| TX0N | H15 | Output | Inverting and non-inverting 50-Ω driver outputs. Compatible with AC-coupled differential inputs. These outputs are AC coupled with 220-nF capacitors assembled on the package substrate. |
| TX0P | G15 | Output | |

Pin Functions (continued)

| PIN | | I/O | DESCRIPTION |
|---|-----|-------------------|--|
| NAME | NO. | | |
| TX1N | J13 | Output | Inverting and non-inverting 50-Ω driver outputs. Compatible with AC-coupled differential inputs. These outputs are AC coupled with 220-nF capacitors assembled on the package substrate. |
| TX1P | H13 | Output | |
| TX2N | J11 | Output | Inverting and non-inverting 50-Ω driver outputs. Compatible with AC-coupled differential inputs. These outputs are AC coupled with 220-nF capacitors assembled on the package substrate. |
| TX2P | H11 | Output | |
| TX3N | J9 | Output | Inverting and non-inverting 50-Ω driver outputs. Compatible with AC-coupled differential inputs. These outputs are AC coupled with 220-nF capacitors assembled on the package substrate. |
| TX3P | H9 | Output | |
| TX4N | J7 | Output | Inverting and non-inverting 50-Ω driver outputs. Compatible with AC-coupled differential inputs. These outputs are AC coupled with 220-nF capacitors assembled on the package substrate. |
| TX4P | H7 | Output | |
| TX5N | J5 | Output | Inverting and non-inverting 50-Ω driver outputs. Compatible with AC-coupled differential inputs. These outputs are AC coupled with 220-nF capacitors assembled on the package substrate. |
| TX5P | H5 | Output | |
| TX6N | J3 | Output | Inverting and non-inverting 50-Ω driver outputs. Compatible with AC-coupled differential inputs. These outputs are AC coupled with 220-nF capacitors assembled on the package substrate. |
| TX6P | H3 | Output | |
| TX7N | H1 | Output | Inverting and non-inverting 50-Ω driver outputs. Compatible with AC-coupled differential inputs. These outputs are AC coupled with 220-nF capacitors assembled on the package substrate. |
| TX7P | G1 | Output | |
| CALIBRATION CLOCK PINS (FOR SUPPORTING UPGRADE PATH TO PIN-COMPATIBLE RETIMER DEVICE) | | | |
| CAL_CLK_IN | E1 | Input | 25-MHz (±100 PPM) 2.5-V single-ended clock from external oscillator. No stringent phase noise or jitter requirements on this clock. A 25-MHz input clock is only required if there is a need to support a future upgrade to the pin-compatible Retimer device. If there is no need to support a future upgrade to a pin-compatible Retimer device, then a 25-MHz clock is not required. this pin can be left floating. This input pin has a weak active pull down and can be left floating if the CAL_CLK feature is not required. |
| CAL_CLK_O UT | E15 | Output | 2.5-V buffered replica of calibration clock input (pin E1) for connecting multiple devices in a daisy-chained fashion. |
| SYSTEM MANAGEMENT BUS (SMBus) PINS | | | |
| ADDR0 | D13 | Input, 4-Level | 4-level strap pins used to set the SMBus address of the device. The pin state is read on power-up. The multi-level nature of these pins allows for 16 unique device addresses. The four strap options include: 0: 1 kΩ to GND R: 10 kΩ to GND F: Float 1: 1 kΩ to VDD |
| ADDR1 | E13 | Input, 4-Level | |
| ALL_DONE_ N | D3 | Output, LVCMOS | Indicates the completion of a valid EEPROM register load operation when in SMBus master mode (EN_SMB = Float): High = External EEPROM load failed or incomplete. Low = External EEPROM load successful and complete. When in SMBus slave mode (EN_SMB = 1), this output will be high-Z until READ_EN_N is driven low, at which point ALL_DONE_N will be driven low. This behavior allows the reset signal connected to READ_EN_N of one device to propagate to the subsequent devices when ALL_DONE_N is connected to READ_EN_N in an SMBus slave mode application. |
| EN_SMB | E3 | Input, 4-Level | 4-level 2.5 V input used to select between SMBus master mode (float) and SMBus slave mode (high). The four defined levels are: 0: 1 kΩ to GND - RESERVED R: 10 kΩ to GND - RESERVED F: Float - SMBus master mode 1: 1 kΩ to VDD - SMBus slave mode |

Pin Functions (continued)

| PIN | | I/O | DESCRIPTION |
|--------------------|---|-------------------------------------|---|
| NAME | NO. | | |
| READ_EN_N | F13 | Input, LVCMOS | Pin has weak pull-up. This pin is 3.3 V tolerant. SMBus master mode (EN_SMB = Float): When asserted low, initiates the SMBus master mode EEPROM read function. Once EEPROM read is complete (indicated by assertion of ALL_DONE_N low), this pin can be held low for normal device operation. SMBus slave mode (EN_SMB = 1): When asserted low, this causes the device to be held in reset (SMBus state machine reset and register reset). This pin should be pulled high or left floating for normal operation in SMBus slave mode. |
| SDA | E12 | I/O, 3.3-V LVCMOS, Open Drain | SMBus data input or open drain output. External 2 -Ω to 5-kΩ pull-up resistor is required. This pin is 3.3-V LVCMOS tolerant. |
| SDC | F12 | I/O, 3.3-V LVCMOS, Open Drain | SMBus clock input or open drain clock output. External 2-kΩ to 5-kΩ pull-up resistor is required. This pin is 3.3-V LVCMOS tolerant. |
| MISCELLANEOUS PINS | | | |
| INT_N | F3 | No Connect | No connect on package. For applications using multiple repeaters and retimers, this pin should be connected to other devices' INT_N pins. This is only a recommendation for cases where there is a need to support a potential future upgrade to the pin-compatible retimer device, which uses this pin as an interrupt signal to a system controller. |
| TEST0 | E2 | Input, LVCMOS | Reserved test pin. During normal (non-test-mode) operation, this pin is configured as an input and therefore is not affected by the presence of a signal. This pin may be left floating, tied to GND, or connected to a 2.5-V (max) output. |
| TEST1 | E14 | Input, LVCMOS | |
| POWER | | | |
| GND | A1, A2, A4, A6, A8, A10, A12, A14, A15, B2, B4, B6, B8, B10, B12, B14, C2, C3, C4, C5, C6, C7, C8, C9, C10, C11, C12, C13, C14, D1, D2, D4, D5, D7, D9, D11, D12, D14, D15, E4, E11, F1, F2, F4, F5, F7, F9, F11, F14, F15, G2, G3, G4, G5, G6, G7, G8, G9, G10, G11, G12, G13, G14, H2, H4, H6, H8, H10, H12, H14, J1, J2, J4, J6, J8, J10, J12, J14, J15 | Power | Ground reference. The GND pins on this device should be connected through a low-impedance path to the board GND plane. |
| VDD | D6, D8, D10, E5, E6, E7, E8, E9, E10, F6, F8, F10 | Power | Power supply, VDD = 2.5 V ±5%. Use at least six de-coupling capacitors between the Repeater's VDD plane and GND as close to the Repeater as possible. For example, four 0.1-μF capacitors and two 1-μF capacitors directly beneath the device or as close to the VDD pins as possible. The VDD pins on this device should be connected through a low-resistance path to the board VDD plane. For more information, see Power Supply Recommendations . |

6 Specifications

6.1 Absolute Maximum Ratings

Over operating free-air temperature range (unless otherwise noted). ⁽¹⁾

| | | MIN | MAX | UNIT |
|----------------------------|--|------|------|------|
| VDD_ABSMAX | Supply voltage (VDD) | −0.5 | 2.75 | V |
| VIO _{2.5V,ABSMAX} | 2.5 V I/O voltage (LVCMOS and CMOS) | −0.5 | 2.75 | V |
| VIO _{3.3V,ABSMAX} | Open drain and 3.3 V-tolerance I/O voltage (SDA, SDC, READ_EN_N) | −0.5 | 4 | V |
| VIO _{HS,ABSMAX} | High-speed I/O voltage (RXnP, RXnN, TXnP, TXnN) | −0.5 | 2.75 | V |
| TJ_ABSMAX | Junction temperature | | 150 | °C |
| T _{stg} | Storage temperature | −40 | 150 | °C |

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

6.2 ESD Ratings

| | | VALUE | UNIT |
|--|--|-------|------|
| V _(ESD) Electrostatic discharge | Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾ | ±2000 | V |
| | Charged-device model (CDM), per JEDEC specification JESD22-C101 ⁽²⁾ | ±1000 | |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process. Pins listed as ±2 kV may actually have higher performance.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

Over operating free-air temperature range (unless otherwise noted).

| | | | MIN | NOM | MAX | UNIT |
|----------------------|--|---|-------|-----|-------|------|
| VDD | Supply voltage, VDD to GND | DC plus AC power should not exceed these limits | 2.375 | 2.5 | 2.625 | V |
| N _{VDD} | Supply noise tolerance ⁽¹⁾ | Supply noise, DC to <50 Hz, sinusoidal | | | 250 | mVpp |
| | | Supply noise, 50 Hz to 10 MHz, sinusoidal | | | 20 | mVpp |
| | | Supply noise, >10 MHz, sinusoidal | | | 10 | mVpp |
| T _{RampVDD} | VDD supply ramp time | From 0 V to 2.375 V | 150 | | | µs |
| T _J | Operating junction temperature | | −40 | | 110 | C |
| T _A | Operating ambient temperature | | −40 | | 85 | C |
| VDD _{SMBUS} | SMBus SDA and SDC Open Drain Termination Voltage | Supply voltage for open drain pull-up resistor | | | 3.6 | V |
| F _{SMBus} | SMBus clock (SDC) frequency in SMBus slave mode | | | | 400 | kHz |

- (1) Sinusoidal noise is superimposed to supply voltage with negligible impact to device function or critical performance shown in the Electrical Table.

6.4 Thermal Information

| THERMAL METRIC ⁽¹⁾ | CONDITIONS / ASSUMPTIONS | VALUE | UNIT |
|---|----------------------------|-------|------|
| R _{θJA} Junction-to-ambient thermal resistance | 4-layer JEDEC board | 44.8 | °C/W |
| | 10-layer 8-in x 6-in board | 26.8 | |
| | 20-layer 8-in x 6-in board | 25.1 | |
| | 30-layer 8-in x 6-in board | 25.4 | |

- (1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report, [SPRA953](#).

Thermal Information (continued)

| THERMAL METRIC ⁽¹⁾ | | CONDITIONS / ASSUMPTIONS | VALUE | UNIT |
|-------------------------------|--|----------------------------|-------|------|
| $R_{\theta JC(top)}$ | Junction-to-case (top) thermal resistance | | 26.5 | °C/W |
| $R_{\theta JB}$ | Junction-to-board thermal resistance | | 28.4 | °C/W |
| Ψ_{JT} | Junction-to-top characterization parameter | 4-layer JEDEC board | 13.1 | °C/W |
| | | 10-layer 8-in x 6-in board | 13.1 | |
| | | 20-layer 8-in x 6-in board | 13.2 | |
| | | 30-layer 8-in x 6-in board | 13.2 | |
| Ψ_{JB} | Junction-to-board characterization parameter | 4-layer JEDEC board | 25.4 | °C/W |
| | | 10-layer 8-in x 6-in board | 22.2 | |
| | | 20-layer 8-in x 6-in board | 21.8 | |
| | | 30-layer 8-in x 6-in board | 21.7 | |

6.5 Electrical Characteristics

Over operating free-air temperature range (unless otherwise noted).

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------|--|--|-----|-----|--------------------|------|
| POWER | | | | | | |
| $W_{channel}$ | Power consumption per active channel | Channel enabled and in linear mode with maximum driver VOD (DRV_SEL_VOD = 3). Static power consumption not included. | | 82 | 97 ⁽¹⁾ | mW |
| | | Channel enabled and in linear mode with minimum driver VOD (DRV_SEL_VOD = 0). Static power consumption not included. | | 75 | 89 ⁽¹⁾ | mW |
| $W_{channel_FIR}$ | Power consumption per active channel | Channel enabled and in FIR limiting mode with C0 = 31 and maximum driver VOD (DRV_SEL_VOD = 3). Static power consumption not included. | | 105 | 123 ⁽¹⁾ | mW |
| | | Channel enabled and in FIR limiting mode with C0 = 31 and minimum driver VOD (DRV_SEL_VOD = 0). Static power consumption not included. | | 97 | 115 ⁽¹⁾ | mW |
| W_{static_total} | Idle (static) mode total device power consumption | Channels disabled and powered down (DRV_PD = 1, EQ_PD = 1). | | 110 | 132 ⁽¹⁾ | mW |
| I_{total} | Active mode total device supply current consumption | All channels enabled and in linear mode with maximum driver VOD (DRV_SEL_VOD = 3). | | 307 | 347 | mA |
| | | All channels enabled and in linear mode with minimum driver VOD (DRV_SEL_VOD = 0). | | 283 | 322 | mA |
| I_{total_FIR} | Active mode total device supply current consumption | All channels enabled and in FIR limiting mode with C0 = 31 and maximum driver VOD (DRV_SEL_VOD = 3). | | 380 | 426 | mA |
| | | All channels enabled and in FIR limiting mode with C0 = 31 and minimum driver VOD (DRV_SEL_VOD = 0). | | 355 | 401 | mA |
| I_{static_total} | Idle (static) mode total device supply current consumption | All channels disabled and powered down (DRV_PD = 1, EQ_PD = 1). | | 44 | 50 | mA |

(1) Max values assume VDD = 2.5 V + 5%.

Electrical Characteristics (continued)

Over operating free-air temperature range (unless otherwise noted).

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|------------------------------|---|------------|------|-----|------|
| LVCMOS DC SPECIFICATIONS (CAL_CLK_IN, CAL_CLK_OUT, READ_EN_N, ALL_DONE_N, TEST[1:0]) | | | | | | |
| V _{IH} | High level input voltage | | 1.75 | VDD | | V |
| | | READ_EN_N pin only | 1.75 | 3.6 | | V |
| V _{IL} | Low level input voltage | | GND | 0.7 | | V |
| V _{OH} | High level output voltage | IOH = 4 mA | 2 | | | V |
| V _{OL} | Low level output voltage | IOL = −4 mA | | 0.4 | | V |
| I _{IH} | Input high leakage current | Vinput = VDD, TEST[1:0] pins | | 16 | | μA |
| | | Vinput = VDD, CAL_CLK_IN pin | | 66 | | μA |
| | | Vinput = VDD, READ_EN_N pin ⁽²⁾ | | 1 | | μA |
| I _{IL} | Input low leakage current | Vinput = 0 V, TEST[1:0] pins | −38 | | | μA |
| | | Vinput = 0 V, CAL_CLK_IN pin ⁽³⁾ | −1 | | | μA |
| | | Vinput = 0 V, READ_EN_N pin ⁽²⁾ | −55 | | | μA |
| 4-LEVEL LOGIC ELECTRICAL SPECIFICATIONS (APPLIES TO 4-LEVEL INPUT CONTROL PINS ADDR0, ADDR1, and EN_SMB) | | | | | | |
| I _{IH} | Input high leakage current | | | 105 | | μA |
| I _{IL} | Input low leakage current | | −253 | | | μA |
| V _{TH} | High level (1) input voltage | | 0.95 × VDD | | | V |
| | Float level input voltage | | 0.67 × VDD | | | V |
| | 10K to GND input voltage | | 0.33 × VDD | | | V |
| | Low level (0) input voltage | | 0.1 | | | V |
| HIGH-SPEED DIFFERENTIAL INPUTS (RXnP, RXnN) | | | | | | |
| BST | CTLE high-frequency boost | Measured with maximum CTLE setting and maximum BW setting (EQ_BST1 = 7, EQ_BST2 = 7, EQ_BW = 3). Boost is defined as the gain at 14 GHz relative to 20 MHz. | | 22.5 | | dB |
| | | Measured with maximum CTLE setting and maximum BW setting (EQ_BST1 = 7, EQ_BST2 = 7, EQ_BW = 3). Boost is defined as the gain at 12.9 GHz relative to 20 MHz. | | 23 | | dB |
| BST | CTLE high-frequency boost | Measured with minimum CTLE setting and minimum BW setting (EQ_BST1 = 0, EQ_BST2 = 0, EQ_BW = 0, EQ_EN_BYPASS = 1). Boost is defined as the gain at 14 Ghz relative to 20 MHz. | | 0.5 | | dB |
| | | Measured with minimum CTLE setting and minimum BW setting (EQ_BST1 = 0, EQ_BST2 = 0, EQ_BW = 0, EQ_EN_BYPASS = 1). Boost is defined as the gain at 12.9 Ghz relative to 20 MHz. | | 1 | | dB |

(2) This pin has an internal weak pull-up.

(3) This pin has an internal weak pull-down.

Electrical Characteristics (continued)

Over operating free-air temperature range (unless otherwise noted).

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|--|-----|-------|-----|------|
| BST _{delta} CTLE high-frequency gain variation | Measured with maximum CTLE setting (EQ_BST1 = 7, EQ_BST2 = 7). Gain variation is defined as the total change in gain at 14 GHz due to temperature and voltage variation. | | < 3 | | dB |
| | Measured with maximum CTLE setting (EQ_BST1 = 7, EQ_BST2 = 7). Gain variation is defined as the total change in gain at 12.9 GHz due to temperature and voltage variation. | | < 3 | | dB |
| BST _{delta} CTLE high-frequency gain variation | Measured with minimum CTLE setting (EQ_BST1 = 0, EQ_BST2 = 0, EQ_EN_BYPASS = 1). Gain variation is defined as the total change in gain at 14 GHz due to temperature and voltage variation. | | < 2 | | dB |
| | Measured with minimum CTLE setting (EQ_BST1 = 0, EQ_BST2 = 0, EQ_EN_BYPASS = 1). Gain variation is defined as the total change in gain at 12.9 GHz due to temperature and voltage variation. | | < 2 | | dB |
| RL _{SDD11} Input differential return loss | 50 MHz to 3.7 GHz | | < -12 | | dB |
| | 3.7 GHz to 10 GHz | | < -10 | | dB |
| | 10 GHz to 14.1 GHz | | < -8 | | dB |
| | 14.1 GHz to 20 GHz | | < -6 | | dB |
| RL _{SDC11} Input differential-to-common-mode return loss | 100 MHz to 3.3 GHz | | < -35 | | dB |
| | 3.3 GHz to 12.9 GHz | | < -26 | | dB |
| | 12.9 GHz to 20 GHz | | < -22 | | dB |
| RL _{SCC11} Input common-mode return loss | 100 MHz to 10 GHz | | < -7 | | dB |
| | 10 GHz to 20 GHz | | < -7 | | dB |
| V _{SDAT} AC signal detect assert (ON) differential voltage threshold level | Minimum input peak-to-peak amplitude level at device pins required to assert signal detect. 25.78125 Gbps with PRBS7 pattern and 20 dB loss channel. | | 196 | | mVpp |
| V _{SDDT} AC signal detect de-assert (OFF) differential voltage threshold level | Maximum input peak-to-peak amplitude level at device pins which causes signal detect to de-assert. 25.78125 Gbps with PRBS7 pattern and 20 dB loss channel. | | 147 | | mVpp |

Electrical Characteristics (continued)

Over operating free-air temperature range (unless otherwise noted).

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|--|--|---|-----|------|-----|------|
| VID _{linear} | Input amplitude linear range. The maximum VID for which the repeater remains linear, defined as ≤1 dB compression of Vout/Vin. | Measured with the highest wide-band gain setting (EQ_HIGH_GAIN = 1, DRV_SEL_VOD = 3). Measured with minimal input channel and minimum EQ using a 1 GHz signal. | | 850 | | mVpp |
| | | Measured with a mid wide-band gain setting (EQ_HIGH_GAIN = 1, DRV_SEL_VOD = 0). Measured with minimal input channel and minimum EQ using a 1 GHz signal. | | 900 | | mVpp |
| | | Measured with a mid wide-band gain setting (EQ_HIGH_GAIN = 0, DRV_SEL_VOD = 3). Measured with minimal input channel and minimum EQ using a 1 GHz signal. | | 1050 | | mVpp |
| | | Measured with the lowest wide-band gain setting (EQ_HIGH_GAIN = 0, DRV_SEL_VOD = 0). Measured with minimal input channel and minimum EQ using a 1 GHz signal. | | 1250 | | mVpp |
| HIGH-SPEED DIFFERENTIAL OUTPUTS (TXnP, TXnN) | | | | | | |
| PRE _{DEM-MAX} | Maximum pre-cursor de-emphasis in FIR limiting mode | Measured with an 16T pattern at 28.125 Gbps using C(0), Reg_0x0B[4:0], set to 0x0C, C(-1), Reg_0x0D[3:0], set to 0xF, and C(+1), Reg_0x0C[3:0], set to 0x0. TX drv_sel_fir, Reg_0x06[0], set to 0x1. | | -11 | | dB |
| PST _{DEM-MAX} | Maximum post-cursor de-emphasis in FIR limiting mode | Measured with an 16T pattern at 28.125 Gbps using C(0), Reg_0x0B[4:0], set to 0x0C, C(-1), Reg_0x0D[3:0], set to 0x0, and C(+1), Reg_0x0C[3:0], set to 0xF. TX drv_sel_fir, Reg_0x06[0], set to 0x1. | | -11 | | dB |
| T _{PRE} | Pre-cursor FIR tap delay in FIR limiting mode | Independent of data rate | | 28 | | ps |
| T _{PST} | Post-cursor FIR tap delay in FIR limiting mode | Independent of data rate | | 25 | | ps |
| VOD _{LIM-MIN} | Minimum differential output amplitude in FIR limiting mode | Measured with a 16T pattern at 25.78125 Gbps using C(0), Reg_0x0B[4:0], set to 0x00, C(-1), Reg_0x0D[3:0], set to 0x0, and C(+1), Reg_0x0C[3:0], set to 0x0. TX drv_sel_fir, Reg_0x06[0], set to 0x1. VOD, Reg_0x06[7:6], set to 0x0. | | 185 | | mVpp |
| | | Measured with a 16T pattern at 25.78125 Gbps using C(0), Reg_0x0B[4:0], set to 0x00, C(-1), Reg_0x0D[3:0], set to 0x0, and C(+1), Reg_0x0C[3:0], set to 0x0. TX drv_sel_fir, Reg_0x06[0], set to 0x1. VOD, Reg_0x06[7:6], set to 0x3. | | 360 | | mVpp |

Electrical Characteristics (continued)

Over operating free-air temperature range (unless otherwise noted).

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------------------|---|--|-------|-----|---------|
| VOD _{LIM-MAX} | Maximum differential output amplitude in FIR limiting mode | | 705 | | mVpp |
| | Measured with a 16T pattern at 25.78125 Gbps using C(0), Reg_0x0B[4:0], set to 0x1F, C(-1), Reg_0x0D[3:0], set to 0x0, and C(+1), Reg_0x0C[3:0], set to 0x0. TX drv_sel_fir, Reg_0x06[0], set to 0x1. VOD, Reg_0x06[7:6], set to 0x0. | | | | |
| | Measured with a 16T pattern at 25.78125 Gbps using C(0), Reg_0x0B[4:0], set to 0x1F, C(-1), Reg_0x0D[3:0], set to 0x0, and C(+1), Reg_0x0C[3:0], set to 0x0. TX drv_sel_fir, Reg_0x06[0], set to 0x1. VOD, Reg_0x06[7:6], set to 0x3. | | 1260 | | mVpp |
| VOD _{idle} | Differential output amplitude, TX disabled or otherwise muted | | < 10 | | mVpp |
| G _{DC} | Vout/Vin wide-band amplitude gain in linear mode | | 4.5 | | dB |
| | Measured with the highest wide-band gain setting (EQ_HIGH_GAIN = 1, DRV_SEL_VOD = 3) at 20 MHz. | | | | |
| | Measured with the lowest wide-band gain setting (EQ_HIGH_GAIN = 0, DRV_SEL_VOD = 0) at 20 MHz. | | –5 | | |
| V _{cm-TX-AC} | Common-mode AC output noise | | 6 | | mV, RMS |
| RJ _{ADD-RMS} | Additive random jitter | | 11 | | fs RMS |
| RL _{SDD22} | Output differential-to-differential return loss | 50 MHz to 4.8 GHz | < –12 | | dB |
| | | 4.8 GHz to 10 GHz | < –11 | | |
| | | 10 GHz to 14.1 GHz | < –7 | | |
| | | 14.1 GHz to 20 GHz | < –6 | | |
| RL _{SCD22} | Output common-mode-to-differential return loss | 50 MHz to 6.0 GHz | < –21 | | dB |
| | | 6.0 GHz to 12.9 GHz | < –22 | | |
| | | 12.9 GHz to 14.1 GHz | < –21 | | |
| | | 14.1 GHz to 20 GHz | < –20 | | |
| RL _{SCC22} | Output common-mode return loss | 50 MHz to 3.3 GHz | < –13 | | dB |
| | | 3.3 GHz to 10.3 GHz | < –11 | | |
| | | 10.3 GHz to 20 GHz | < –8 | | |
| t _r , t _f | Transition time (20%-80%) in FIR limiting mode | Measured at 28.125 Gbps with 16T data pattern using C(0), Reg_0x0B[4:0], set to 0x00, C(-1), Reg_0x0D[3:0], set to 0x0, and C(+1), Reg_0x0C[3:0], set to 0x0. TX drv_sel_fir, Reg_0x06[0], set to 0x1. | 19.9 | | ps |
| | | Measured at 28.125 Gbps with 16T data pattern using C(0), Reg_0x0B[4:0], set to 0x1F, C(-1), Reg_0x0D[3:0], set to 0x0, and C(+1), Reg_0x0C[3:0], set to 0x0. TX drv_sel_fir, Reg_0x06[0], set to 0x1. | 25.8 | | ps |

Electrical Characteristics (continued)

Over operating free-air temperature range (unless otherwise noted).

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-------------------------|---|--|-----|-----|-----|------|
| OTHER PARAMETERS | | | | | | |
| t_D | Input-to-output latency (propagation delay) through a channel | Linear mode | | 100 | | ps |
| t_D | Input-to-output latency (propagation delay) through a channel | FIR limiting mode, Reg_0x06[0]=1 | | 160 | | ps |
| t_{SK} | Channel-to-channel interpair skew | Latency difference between channels | | <14 | | ps |
| T_{EEPROM} | EEPROM configuration load time | Time to assert ALL_DONE_N after REAN_EN_N has been asserted. Single device reading its configuration from an EEPROM with common channel configuration. This time scales with the number of devices reading from the same EEPROM. Does not include power-on reset time. | | | 4 | ms |
| | | Time to assert ALL_DONE_N after REAN_EN_N has been asserted. Single device reading its configuration from an EEPROM. Non-common channel configuration. This time scales with the number of devices reading from the same EEPROM. Does not include power-on reset time. | | | 7 | |
| T_{POR} | Power-on reset assertion time | Internal power-on reset (PoR) stretch between stable power supply and de-assertion of internal PoR. The SMBus address is latched on the completion of the PoR stretch, and SMBus accesses are permitted once PoR completes. | | | 60 | ms |

6.6 Electrical Characteristics -- Serial Management Bus Interface

| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|-----------|--------------------------|---|------|-----|-----|---------|
| V_{IH} | Input high level voltage | SDA and SDC | 1.75 | | 3.6 | V |
| V_{IL} | Input low level voltage | SDA and SDC | GND | | 0.8 | V |
| V_{OL} | Output low level voltage | SDA and SDC, $I_{OL} = 1.25$ mA | GND | | 0.4 | V |
| C_{IN} | Input pin capacitance | SDA and SDC | | 15 | | pF |
| I_{IN} | Input current | SDA or SDC, $V_{INPUT} = V_{IN}, V_{DD}, GND$ | -18 | | 18 | μ A |

6.7 Timing Requirements -- Serial Management Bus Interface

Over operating free-air temperature range (unless otherwise noted).

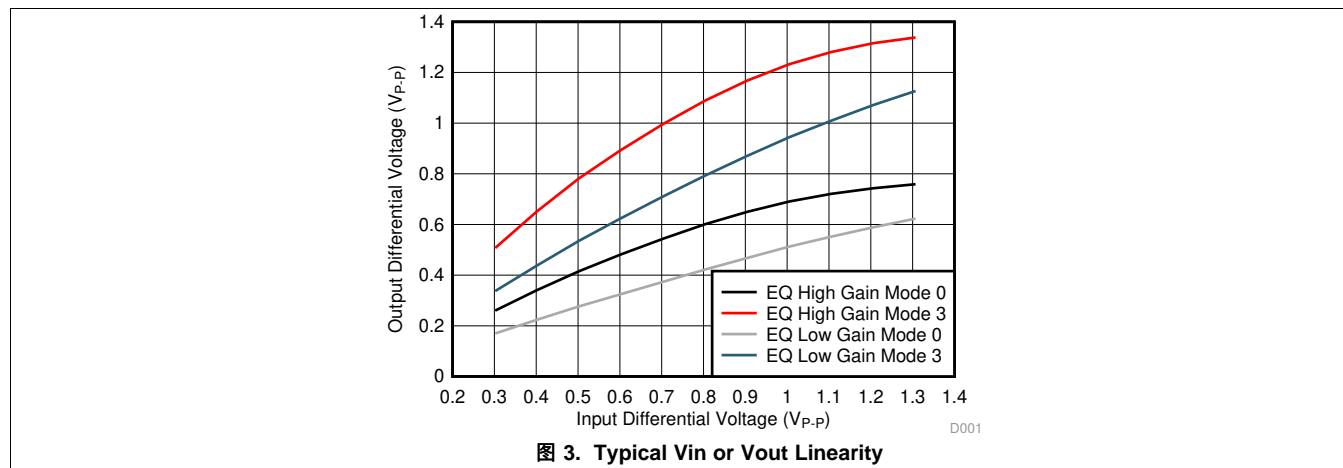
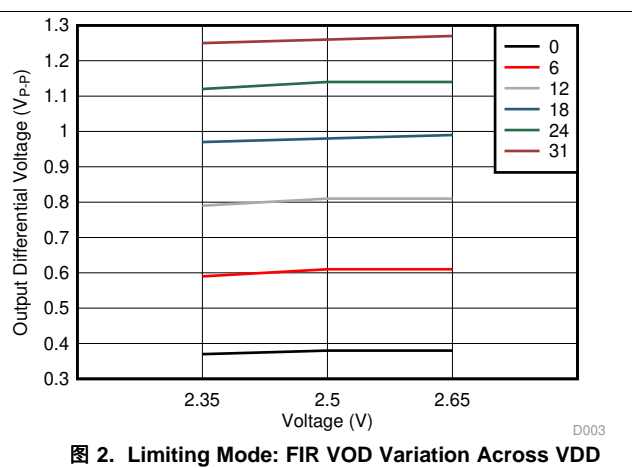
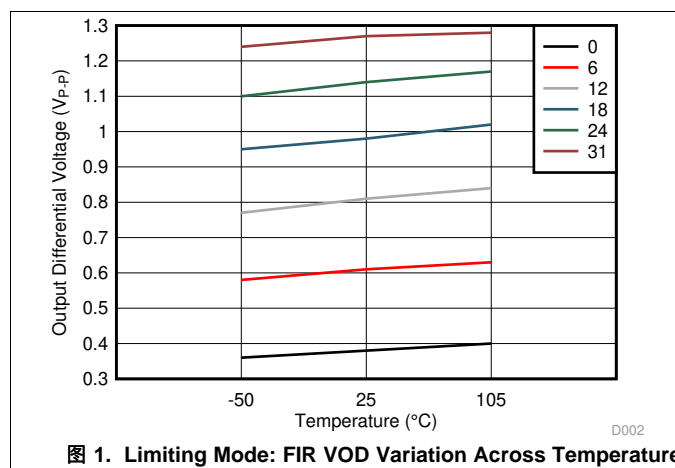
| PARAMETER | | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|---|-------------------------------|---|------|------|------|---------|
| RECOMMENDED SMBus SWITCHING CHARACTERISTICS (SMBus SLAVE MODE) | | | | | | |
| f_{SDC} | SDC clock frequency | EN_SMB = 1 k to VDD (Slave Mode) | 10 | 100 | 400 | kHz |
| T_{SDA-HD} | Data hold time | | | 0.75 | | ns |
| T_{SDA-SU} | Data setup time | | | 100 | | ns |
| T_{SDA-R} | SDA rise time, read operation | Pull-up resistor = 1 k Ω , $C_b = 50$ pF | | 150 | | ns |
| T_{SDA-F} | SDA fall time, read operation | Pull-up resistor = 1 k Ω , $C_b = 50$ pF | | 4.5 | | ns |
| SMBus SWITCHING CHARACTERISTICS (SMBus MASTER MODE) | | | | | | |
| f_{SDC} | SDC clock frequency | EN_SMB = Float (Master Mode) | 260 | 303 | 346 | kHz |
| $T_{SDC-LOW}$ | SDC low period | | 1.66 | 1.90 | 2.21 | μ s |
| $T_{SDC-HIGH}$ | SDC high period | | 1.22 | 1.40 | 1.63 | μ s |
| $T_{HD-START}$ | Hold time start operation | | | 0.6 | | μ s |

Timing Requirements -- Serial Management Bus Interface (continued)

Over operating free-air temperature range (unless otherwise noted).

| PARAMETER | TEST CONDITIONS | MIN | TYP | MAX | UNIT |
|----------------|----------------------------------|---------------------------------|-----|-----|---------|
| $T_{SU-START}$ | Setup time start operation | | 0.6 | | μs |
| T_{SDA-HD} | Data hold time | | 0.9 | | μs |
| T_{SDA-SU} | Data setup time | | 0.1 | | μs |
| $T_{SU-STOP}$ | Stop condition setup time | | 0.6 | | μs |
| T_{BUF} | Bus free time between Stop-Start | | 1.3 | | μs |
| T_{SDC-R} | SDC rise time | Pull-up resistor = 1 k Ω | 300 | | ns |
| T_{SDC-F} | SDFC fall time | Pull-up resistor = 1 k Ω | 300 | | ns |

6.8 Typical Characteristics



7 Detailed Description

7.1 Overview

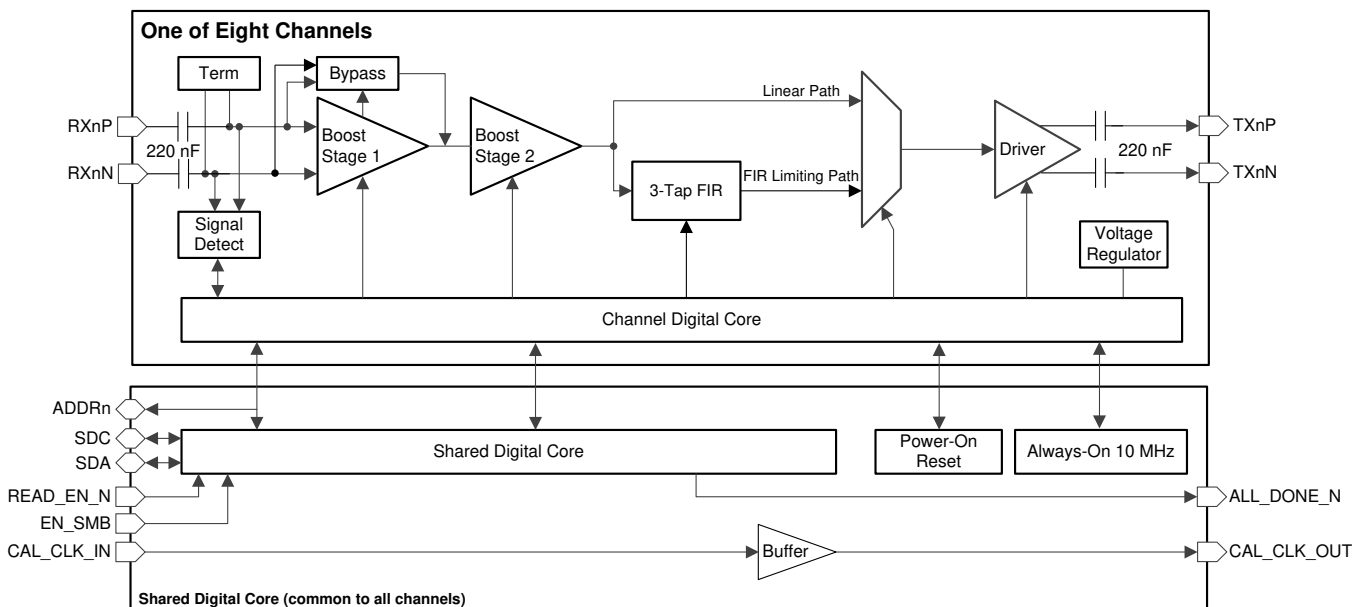
The DS280BR810 is an eight-channel multi-rate linear repeater with integrated signal conditioning. The eight channels operate independently from one another. Each channel includes a continuous-time linear equalizer (CTLE), an optional FIR filter and a linear output driver, which compensate for the presence of a dispersive transmission channel between the source transmitter and the final receiver.

All transmit and receive channels on the DS280BR810 are AC-coupled with physical AC coupling capacitors (220 nF $\pm 20\%$) on the package substrate. This ensures common mode voltage compatibility with all link partners and eliminates the need for AC coupling capacitors on the system PCB, thereby saving cost and greatly reducing PCB routing complexity.

The DS280BR810 is configurable through a single SMBus port. The DS280BR810 can also act as an SMBus master to configure itself from an EEPROM.

The sections which follow describe the functionality of various circuits and features within the DS280BR810. For more information about how to program or operate these features, consult the DS280BR810 Programming Guide.

7.2 Functional Block Diagram



7.3 Feature Description

7.3.1 Device Data Path Operation

The DS280BR810 data path consists of several key blocks as shown in [Functional Block Diagram](#). These key circuits are:

- AC-coupled Receiver and Transmitter
- Signal Detect
- 2-stage CTLE
- Driver DC Gain Control
- FIR Filter
- Data path Mux

Feature Description (接下页)

7.3.2 AC-Coupled Receiver and Transmitter

The differential receiver for each DS280BR810 channel contains an integrated on die $100\ \Omega$ differential termination as well as 220 nF AC coupling capacitors embedded onto the package substrate. The differential transmitter for each DS280BR810 channel also has 220 nF $\pm 20\%$ AC coupling capacitors embedded on the package substrate.

7.3.3 Signal Detect

Each DS280BR810 high speed receiver has a signal detect circuit which monitors the energy level on the inputs. The signal detect circuit will enable the high-speed data path if a signal is detected, or power it off if no signal is detected. By default, this feature is enabled, but can be manually controlled through the SMBus channel registers. This can be useful if it is desired to manually force channels to be disabled. For information on how to manually operate the signal detect circuit refer to the DS280BR810 Programming Guide.

7.3.4 2-Stage CTLE

The continuous-time linear equalizer (CTLE) in the DS280BR810 consists of two stages which are configurable through the SMBus channel registers. This CTLE is designed to be highly linear to allow the DS280BR810 to preserve the transmitter's pre-cursor and post cursor signal characteristics. This highly linear behavior enables the DS280BR810 to be used in applications that use protocols such as link training, where it is important to recover and pass through incremental changes in transmit equalization.

Each stage in the CTLE has 3-bit boost control. The first CTLE stage provides a coarse adjustment of the total boost. Larger settings correspond to higher total boost. The first stage can be bypassed entirely to achieve the lowest possible total boost. The second CTLE stage acts as a fine adjustment on the total boost and impacts the shape of the boost curve accordingly. Larger settings correspond to higher total boost. The bandwidth of the CTLE can be adjusted using a 2-bit bandwidth control. Larger settings correspond to higher total bandwidth. For information on how to program the CTLE refer to the DS280BR810 Programming Guide.

In addition to high-frequency boost, the CTLE can apply wide-band amplitude gain. There are two settings (high-gain and low-gain) which work together with the driver DC gain control to affect the total input-to-output wide-band amplitude gain.

7.3.5 Driver DC Gain Control

In addition to the high-frequency boost provided by the CTLE, the DS280BR810 is also able to provide additional DC or low-frequency gain. The effective DC gain is controlled by a 3-bit field, allowing for eight levels of DC attenuation or DC gain. For information on how to configure the DC gain refer to the DS280BR810 Programming Guide.

7.3.6 FIR Filter (Limiting Mode)

The DS280BR810 has an optional limiting mode with a fixed-delay 3-tap finite impulse response (FIR) filter to provide transmit equalization. This FIR can be configured to apply pre-cursor and post-cursor boost to the high speed signal. The FIR filter also allows for main cursor amplitude control. The tap polarities in the FIR filter are fixed to allow for pre-cursor or post-cursor boost to be applied to the signal.

Feature Description (接下页)

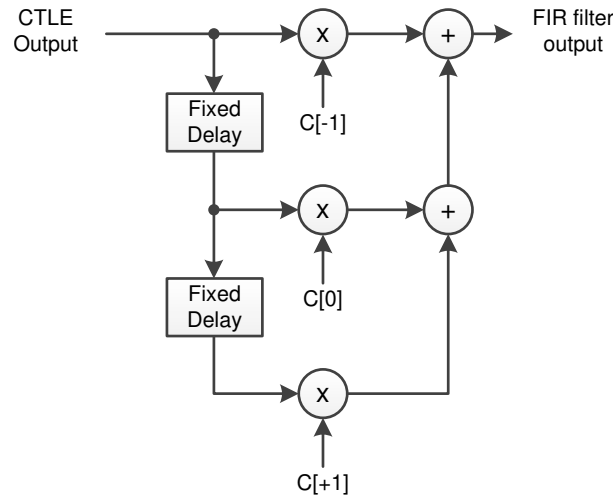


图 4. 3-Tap FIR Filter Block Diagram

Linear mode is recommended for the majority of applications, especially those which require Link Training. Common protocols such as 100 GbE and 40 GbE CR4/KR4, 50 GbE and 25GbE CR, 10 GbE KR, InfiniBand EDR, and others require Link Training. Linear mode is required for Link Training so that the ASIC transmitter precursor and post-cursor coefficients can propagate through the DS280BR810 in a transparent fashion. For applications which do not utilize Link Training, limiting mode may be used to provide output pre-cursor and post-cursor equalization for the purpose of improving the far-end eye opening. If the downstream receiver SerDes uses a decision feedback equalizer (DFE) to equalize the signal, the linear mode may be preferable to the limiting mode. DFE circuits often perform best when operating on a linear signal.

7.3.7 Configurable SMBus Address

The DS280BR810's SMBus slave address is strapped at power up using the ADDR[1:0] pins. The pin state is read on power up, after the internal power-on reset completes. The ADDR[1:0] pins are four-level LVCMOS IOs, which provide for 16 unique SMBus addresses. 表 1 lists the DS280BR810 SMBus slave address options.

表 1. SMBus Address Map

| 7-BIT SLAVE ADDRESS | 8-BIT WRITE ADDRESS | REQUIRED ADDRESS PIN STRAP VALUE | |
|---------------------|---------------------|----------------------------------|-------|
| | | ADDR1 | ADDR0 |
| 0x18 | 0x30 | 0 | 0 |
| 0x19 | 0x32 | 0 | R |
| 0x1A | 0x34 | 0 | F |
| 0x1B | 0x36 | 0 | 1 |
| 0x1C | 0x38 | R | 0 |
| 0x1D | 0x3A | R | R |
| 0x1E | 0x3C | R | F |
| 0x1F | 0x3E | R | 1 |
| 0x20 | 0x40 | F | 0 |
| 0x21 | 0x42 | F | R |
| 0x22 | 0x44 | F | F |
| 0x23 | 0x46 | F | 1 |
| 0x24 | 0x48 | 1 | 0 |
| 0x25 | 0x4A | 1 | R |
| 0x26 | 0x4C | 1 | F |
| 0x27 | 0x4E | 1 | 1 |

7.4 Device Functional Modes

7.4.1 SMBus Slave Mode Configuration

To configure the DS280BR810 for SMBus slave mode connect the EN_SMB pin to VDD with a 1 kΩ resistor. When the DS280BR810 is configured for SMBus slave mode operation the READ_EN_N becomes an active-low reset pin, resetting register values when driven to LOW, or V_{IL} . Additionally, when the DS280BR810 is configured for SMBus slave mode the ALL_DONE_N output pin is high-Z; except for when READ_EN_N is driven LOW which causes ALL_DONE_N to also be driven LOW. Refer to [Register Maps](#) for additional register information.

7.4.2 SMBus Master Mode Configuration (EEPROM Self Load)

To configure the DS280BR810 for SMBus master mode, leave the EN_SMB pin floating (no connect). If the DS280BR810 is configured for SMBus master mode, it will remain in the SMBus IDLE state until the READ_EN_N pin is asserted to LOW. Once the READ_EN_N pin is driven LOW, the DS280BR810 becomes an SMBus master and attempts to self-configure by reading device settings stored in an external EEPROM (SMBus 8-bit address 0xA0). When the DS280BR810 has finished reading from the EEPROM successfully, it will drive the ALL_DONE_N pin LOW and then change from an SMBus master to an SMBus slave. Not all bits in the register map can be configured through an EEPROM load. Refer to the Programming Guide for more information.

When designing a system for using the external EEPROM, the user must follow these specific guidelines:

- Maximum EEPROM size is 8 kb (1024 x 8-bit).
- Set EN_SMB = FLOAT, configure for SMBus master mode.
- The external EEPROM device address byte must be 0xA0 and capable of 400 kHz operation at 2.5 V or 3.3 V supply.
- Configure the ADDR[1:0] inputs to select the SMBus slave address for the DS280BR810. Once the DS280BR810 completes its EEPROM load the device becomes a slave on the control bus.

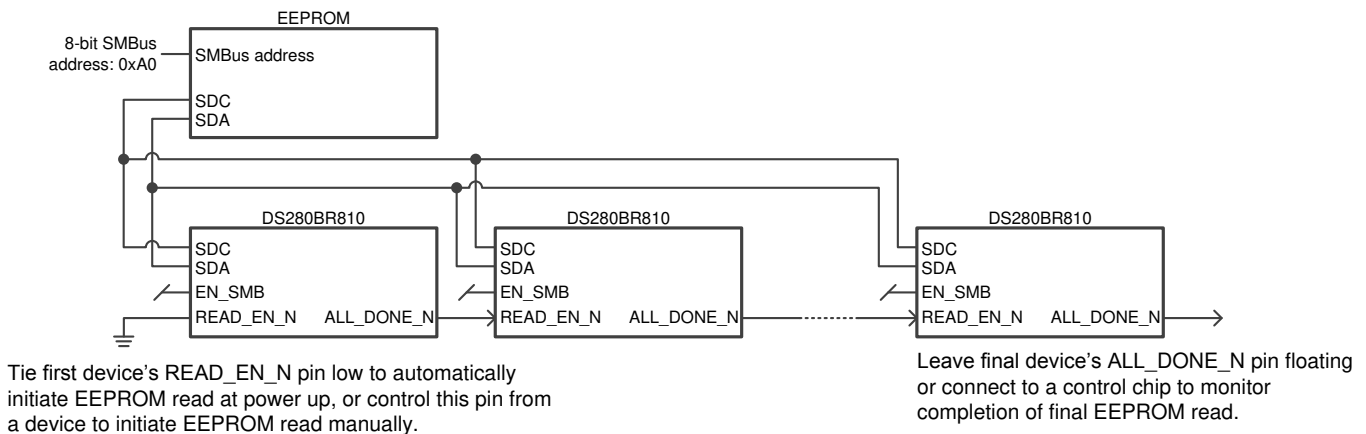


图 5. Example Daisy Chain for Multiple Device Single EEPROM Configuration

When tying multiple DS280BR810 devices to the SDA and SDC bus, use these guidelines to configure the devices for SMBus master mode:

- Use SMBus ADDR[1:0] address bits so that each device can load its configuration from the EEPROM. The example below is for four devices. The first device in the sequence conventionally uses the 8-bit slave write address 0x30, while subsequent devices follow the address order listed below.
 - DS280BR810 instance 1 (U1): ADDR[1:0] = {0, 0} = 0x30
 - DS280BR810 instance 2 (U2): ADDR[1:0] = {0, R} = 0x32
 - DS280BR810 instance 3 (U3): ADDR[1:0] = {0, F} = 0x34
 - DS280BR810 instance 4 (U4): ADDR[1:0] = {0, 1} = 0x36
- Use a pull-up resistor on SDA and SDC; resistor value = 2 kΩ to 5 kΩ is adequate.
- Float (no connect) the EN_SMB pin (E3) on all DS280BR810 devices to configure them for SMBus master mode. The EN_SMB pin should not be dynamically changed between the high and float states.

Device Functional Modes (接下页)

- Daisy-chain READ_EN_N (pin F13) and ALL_DONE_N (pin D3) from one device to the next device in the following sequence so that they do not compete for master control of the EEPROM at the same time.
 1. Tie READ_EN_N of the first device in the chain (U1) to GND to trigger EEPROM read immediately after the DS280BR810 power-on reset (PoR) completes. Alternatively, drive the READ_EN_N pin from a control device (micro-controller or FPGA) to trigger the EEPROM read at a specific time.
 2. Tie ALL_DONE_N of U1 to READ_EN_N of U2
 3. Tie ALL_DONE_N of U2 to READ_EN_N of U3
 4. Tie ALL_DONE_N of U3 to READ_EN_N of U4
 5. Optional: Tie ALL_DONE_N output of U4 to a micro-controller or an LED to show the devices have been loaded successfully.

Once the ALL_DONE_N status pin of the last device is flagged to indicate that all devices sharing the SMBus line have been successfully programmed, control of the SMBus line is released by the DS280BR810. The device then reverts back to SMBus slave mode. At this point, an external MCU can perform any additional Read or Write operations to the DS280BR810.

Refer to the Programming Guide for additional information concerning SMBus master mode.

7.5 Programming

The DS280BR810 can be programmed in two ways. The DS280BR810 can be configured as an SMBus slave (EN_SMB = HIGH) or the device can temporarily act as an SMBus master and load its configuration settings from an external EEPROM (EN_SMB = FLOAT). Refer to [SMBus Slave Mode Configuration](#) and [SMBus Master Mode Configuration \(EEPROM Self Load\)](#) for details.

7.5.1 Transfer of Data with the SMBus Interface

The System Management Bus (SMBus) is a two-wire serial interface through which a master can communicate with various system components. Slave devices are identified by a unique device address. The two-wire serial interface consists of SDC and SDA signals. SDC is a clock output from the master to all of the slave devices on the bus. SDA is a bidirectional data signal between the master and slave devices. The DS280BR810 SMBus, SDC, and SDA signals are open drain and require external pull-up resistors.

Start and Stop Conditions:

The master generates Start and Stop conditions at the beginning and end of each transaction:

- Start: High to LOW transition (falling edge) of SDA while SDC is HIGH.
- Stop: Low to HIGH transition (rising edge) of SDA while SDC is HIGH.

The master generates 9 clock pulses for each byte transfer. The 9th clock pulse constitutes the acknowledge (ACK) cycle. The transmitter releases SDA to allow the receiver to send the ACK signal. An ACK is when the device pulls SDA LOW, while a NACK (no acknowledge) is recorded if the line remains HIGH.

Writing data from a master to a slave consists of three parts:

- The master begins with a start condition followed by the slave device address with the R/W bit cleared.
- The master sends the 8-bit register address that will be written.
- The master sends the data byte to write for the selected register address. The register address pointer will then increment, so the master can send the data byte for the subsequent register without re-addressing the device, if desired. The final data byte to write should be followed by a stop condition.

SMBus read operations consist of four parts:

- The master initiates the read cycle with start condition followed by slave device address with the R/W bit cleared.
- The master sends the 8-bit register address that will be read.
- After acknowledgment from the slave, the master initiates a re-start condition.
- The slave device address is resent followed with R/W bit set.
- After acknowledgment from the slave, the data is read back from the slave to the master. The last ACK is HIGH if there are no more bytes to read.

7.6 Register Maps

Many of the registers in the DS280BR810 are divided into bit fields. This allows a single register to serve multiple purposes which may be unrelated. Often, configuring the DS280BR810 requires writing a bit field that makes up only part of a register value while leaving the remainder of the register value unchanged. The procedure for accomplishing this task is to read in the current value of the register to be written, modify only the desired bits in this value, and write the modified value back to the register. This sequence is commonly referred to as Read-Modify-Write. If the entire register is to be changed, rather than just a bit field within the register, it is not necessary to read in the current value of the register first.

Most register bits can be read or written to. However, some register bits are constrained to specific interface instructions.

Register bits can have the following interface constraints:

- R - Read only
- RW - Read/Write
- RWSC - Read/Write, Self-Clearing

7.6.1 Register Types: Global, Shared, and Channel

The DS280BR810 has 3 types of registers:

1. Global Registers - These registers can be accessed at any time and are used to select between individual channel registers and shared registers, or to read back the TI ID and version information.
2. Shared Registers - These registers are used for device-level configuration, status read back or control. Set register 0xFF[0] = 0 and configure 0xFF[5:4] to access the shared registers.
3. Channel Registers – These registers are used to control and configure specific features for each individual channel. All channels have the same channel register set and can be configured independent of each other. Set register 0xFF[0] = 1 and configure register 0xFC to access the desired channel register set.

Refer to the Programming Guide for additional information on register configuration.

7.6.2 Global Registers: Channel Selection and ID Information

The global registers can be accessed at any time, regardless of whether the shared or channel register set is selected. The DS280BR810 global registers are located at address 0xEF - 0xFF.

表 2. Global Register Map

| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|------------|-----|---------------|------|--------|-----------------------|---|
| 0xEF | | 0x0C | | | General | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 1 | R | N | DEVICE_ID_QUAD_CNT[3] | TI device ID (quad count). Contains 0x0C. |
| | 2 | 1 | R | N | DEVICE_ID_QUAD_CNT[2] | |
| | 1 | 0 | R | N | DEVICE_ID_QUAD_CNT[1] | |
| | 0 | 0 | R | N | DEVICE_ID_QUAD_CNT[0] | |

Register Maps (接下页)

表 2. Global Register Map (接下页)

| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|-------------|-----|---------------|------|--------|-------------------------|---|
| 0xF0 | | 0x00 | | | Version Revision | |
| | 7 | 0 | R | N | TYPE | TI version ID. Contains 0x00. |
| | 6 | 0 | R | N | VERSION[6] | |
| | 5 | 0 | R | N | VERSION[5] | |
| | 4 | 0 | R | N | VERSION[4] | |
| | 3 | 0 | R | N | VERSION[3] | |
| | 2 | 0 | R | N | VERSION[2] | |
| | 1 | 0 | R | N | VERSION[1] | |
| | 0 | 0 | R | N | VERSION[0] | |
| 0xF1 | | 0x40 | | | Channel Control | |
| | 7 | 0 | R | N | DEVICE_ID[7] | TI device ID. Contains 0x40. |
| | 6 | 1 | R | N | DEVICE_ID[6] | |
| | 5 | 0 | R | N | DEVICE_ID[5] | |
| | 4 | 0 | R | N | DEVICE_ID[4] | |
| | 3 | 0 | R | N | DEVICE_ID[3] | |
| | 2 | 0 | R | N | DEVICE_ID[2] | |
| | 1 | 0 | R | N | DEVICE_ID[1] | |
| | 0 | 0 | R | N | DEVICE_ID[0] | |
| 0xF3 | | 0x00 | | | Channel Control | |
| | 7 | 0 | R | N | CHAN_VERSION[3] | TI digital channel version ID. Contains 0x00. |
| | 6 | 0 | R | N | CHAN_VERSION[2] | |
| | 5 | 0 | R | N | CHAN_VERSION[1] | |
| | 4 | 0 | R | N | CHAN_VERSION[0] | |
| | 3 | 0 | R | N | SHARE_VERSION[3] | TI digital share version ID. Contains 0x00. |
| | 2 | 0 | R | N | SHARE_VERSION[2] | |
| | 1 | 0 | R | N | SHARE_VERSION[1] | |
| | 0 | 0 | R | N | SHARE_VERSION[0] | |
| 0xFC | | 0x00 | | | General | |
| | 7 | 0 | RW | N | EN_CH7 | Select channel 7 |
| | 6 | 0 | RW | N | EN_CH6 | Select channel 6 |
| | 5 | 0 | RW | N | EN_CH5 | Select channel 5 |
| | 4 | 0 | RW | N | EN_CH4 | Select channel 4 |
| | 3 | 0 | RW | N | EN_CH3 | Select channel 3 |
| | 2 | 0 | RW | N | EN_CH2 | Select channel 2 |
| | 1 | 0 | RW | N | EN_CH1 | Select channel 1 |
| | 0 | 0 | RW | N | EN_CH0 | Select channel 0 |
| 0xFD | | 0x00 | | | | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RESERVED | RESERVED |

Register Maps (接下页)

表 2. Global Register Map (接下页)

| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|-------------|-----|---------------|------|--------|------------------------|--|
| 0xFE | | 0x03 | | | Vendor ID | |
| | 7 | 0 | R | N | VENDOR_ID[7] | TI vendor ID. Contains 0x03. |
| | 6 | 0 | R | N | VENDOR_ID[6] | |
| | 5 | 0 | R | N | VENDOR_ID[5] | |
| | 4 | 0 | R | N | VENDOR_ID[4] | |
| | 3 | 0 | R | N | VENDOR_ID[3] | |
| | 2 | 0 | R | N | VENDOR_ID[2] | |
| | 1 | 1 | R | N | VENDOR_ID[1] | |
| | 0 | 1 | R | N | VENDOR_ID[0] | |
| 0xFF | | 0x10 | | | Channel Control | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 0 | RW | N | EN_SHARE_Q1 | Select shared registers for Quad 1 (Channels 4-7). |
| | 4 | 1 | RW | N | EN_SHARE_Q0 | Select shared registers for Quad 0 (Channels 0-3). |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | WRITE_ALL_CH | Allows customer to write to all channels as if they are the same, but only allows to read back from the channel specified in 0xFC and 0xFD. Note: EN_CH_SMB must be = 1 or else this function is invalid. |
| | 0 | 0 | RW | N | EN_CH_SMB | 1: Enables SMBus access to the channels specified in register 0xFC. 0: The shared registers are selected, see 0xFF[5:4]. |

7.6.3 Shared Registers

表 3. Shared Register Map

| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|-------------|-----|---------------|------|--------|-----------------------------|--|
| 0x00 | | 0x0C | | | General | |
| | 7 | 0 | R | N | I ² C_ADDR[3] | I ² C strap observation. The device 7-bit slave address is 0x18 + I ² C_ADDR[3:0]. |
| | 6 | 0 | R | N | I ² C_ADDR[2] | |
| | 5 | 0 | R | N | I ² C_ADDR[1] | |
| | 4 | 0 | R | N | I ² C_ADDR[0] | |
| | 3 | 0 | R | N | RESERVED | RESERVED |
| | 2 | 0 | R | N | RESERVED | RESERVED |
| | 1 | 0 | R | N | RESERVED | RESERVED |
| | 0 | 0 | R | N | RESERVED | RESERVED |
| 0x01 | | 0x00 | | | Version Revision | |
| | 7 | 0 | R | N | RESERVED | RESERVED |
| | 6 | 0 | R | N | RESERVED | RESERVED |
| | 5 | 0 | R | N | RESERVED | RESERVED |
| | 4 | 0 | R | N | RESERVED | RESERVED |
| | 3 | 0 | R | N | RESERVED | RESERVED |
| | 2 | 0 | R | N | RESERVED | RESERVED |
| | 1 | 0 | R | N | RESERVED | RESERVED |
| | 0 | 0 | R | N | RESERVED | RESERVED |
| 0x02 | | 0x00 | | | Channel Control | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RESERVED | RESERVED |
| 0x03 | | 0x00 | | | Channel Control | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RESERVED | RESERVED |
| 0x04 | | 0x01 | | | General | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RWSC | N | RST_I ² C_REGS | 1: Reset shared registers, bit is self-clearing. 0: Normal operation |
| | 5 | 0 | RWSC | N | RST_I ² C_MAS | 1: Self-clearing reset for I ² C master. 0: Normal operation |
| | 4 | 0 | RW | N | FRC_EEPRM_RD | 1: Override EN_SMB and input chain status to force EEPROM Configuration. 0: Normal operation |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | REGS_CLOCK_EN | RESERVED |
| | 1 | 0 | RW | N | I ² C_MAS_CLK_EN | RESERVED |
| | 0 | 1 | RW | N | I ² CSLV_CLK_EN | RESERVED |

表 3. Shared Register Map (接下页)

| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|-------------|-----|---------------|------|--------|---------------------|---|
| 0x05 | | 0x00 | | | General | |
| | 7 | 0 | RW | N | DISAB_EEPRM_CFG | 1: Disable Master Mode EEPROM Configuration (If not started, not effective midway or after configuration). 0: Normal operation |
| | 6 | 0 | RW | N | CRC_EN | RESERVED |
| | 5 | 0 | RW | N | ML_TEST_CONTROL | RESERVED |
| | 4 | 0 | R | N | EEPROM_READING_DONE | Sets 1 when EEPROM reading done. |
| | 3 | 0 | R | N | RESERVED | RESERVED |
| | 2 | 0 | R | Y | CAL_CLK_INV_DIS | 1: Disable the inversion of CAL_CLK_OUT. 0: Normal operation, CAL_CLK_OUT is inverted with respect to CAL_CLK_IN. |
| | 1 | 0 | R | N | RESERVED | RESERVED |
| | 0 | 0 | R | N | TEST0_AS_CAL_CLK | RESERVED |
| 0x06 | | 0x00 | | | General | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RESERVED | RESERVED |
| 0x07 | | 0x00 | | | General | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | R | N | CAL_CLK_DET | 1: Indicates that CAL_CLK has been detected. 0: Indicates that CAL_CLK has not been detected. |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | N | MR_CAL_CLK_DET_DIS | 1: Disable CAL_CLK detect. 0: Enable CAL_CLK detect. |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | Y | DIS_CAL_CLK_OUT | 1: Disable CAL_CLK_OUT, output is high-Z. 0: Enable CAL_CLK_OUT. |
| 0x08 | | 0x00 | | | General | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RESERVED | RESERVED |
| 0x09 | | 0x00 | | | General | |
| | 7 | 0 | R | N | RESERVED | RESERVED |
| | 6 | 0 | R | N | RESERVED | RESERVED |
| | 5 | 0 | R | N | RESERVED | RESERVED |
| | 4 | 0 | R | N | RESERVED | RESERVED |
| | 3 | 0 | R | N | RESERVED | RESERVED |

表 3. Shared Register Map (接下页)

| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|-------------|-----|---------------|------|--------|--------------------------------|---|
| | 2 | 0 | R | N | RESERVED | RESERVED |
| | 1 | 0 | R | N | RESERVED | RESERVED |
| | 0 | 0 | R | N | RESERVED | RESERVED |
| 0x0A | | 0x00 | | | General | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | R | N | RESERVED | RESERVED |
| | 0 | 0 | R | N | RESERVED | RESERVED |
| 0x0B | | 0x00 | | | | |
| | 7 | 0 | R | N | EECFG_CMPLT | 11: Not valid. 10: EEPROM load completed successfully. |
| | 6 | 0 | R | N | EECFG_FAIL | 01: EEPROM load failed after 64 attempts. 00: EEPROM load in progress. |
| | 5 | 0 | R | N | EECFG_ATMPT[5] | Indicates number of attempts made to load EEPROM image. |
| | 4 | 0 | R | N | EECFG_ATMPT[4] | |
| | 3 | 0 | R | N | EECFG_ATMPT[3] | |
| | 2 | 0 | R | N | EECFG_ATMPT[2] | |
| | 1 | 0 | R | N | EECFG_ATMPT[1] | |
| | 0 | 0 | R | N | EECFG_ATMPT[0] | |
| 0x0C | | 0x91 | | | | |
| | 7 | 1 | RW | N | I ² C_FAST | 1: EEPROM load uses Fast I ² C Mode (400 kHz). 0: EEPROM load uses Standard I ² C Mode (100 kHz). |
| | 6 | 0 | RW | N | I ² C_SDA_HOLD[2] | Internal SDA Hold Time This field configures the amount of internal hold time provided for the SDA input relative to the SDC input. Units are 100 ns. |
| | 5 | 0 | RW | N | I ² C_SDA_HOLD[1] | |
| | 4 | 1 | RW | N | I ² C_SDA_HOLD[0] | |
| | 3 | 0 | RW | N | I ² C_FLTR_DEPTH[3] | I ² C Glitch Filter Depth This field configures the maximum width of glitch pulses on the SDC and SDA inputs that will be rejected. Units are 100 ns. |
| | 2 | 0 | RW | N | I ² C_FLTR_DEPTH[2] | |
| | 1 | 0 | RW | N | I ² C_FLTR_DEPTH[1] | |
| | 0 | 1 | RW | N | I ² C_FLTR_DEPTH[0] | |

7.6.4 Channel Registers

表 4. Channel Register Map

| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|-------------|-----|---------------|------|--------|-------------------|---|
| 0x00 | | 0x00 | | | General | |
| | 7 | 0 | RW | N | CLK_CORE_DISAB | 1: Disables 10 M core clock. This is the main clock domain for all the state machines. 0: Normal operation |
| | 6 | 0 | RW | N | CLK_REGS_EN | 1: Force enable the clock to the registers. Normally, the register clock is enabled automatically on a needed basis. 0: Normal operation |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | CLK_REF_DISAB | 1: Disables the 25 MHz CAL_CLK domain. 0: Normal operation |
| | 3 | 0 | RW | N | RST_CORE | 1: Reset the 10 M core clock domain. This is the main clock domain for all the state machines. 0: Normal operation |
| | 2 | 0 | RWSC | N | RST_REGS | 1: Reset channel registers to power-up defaults. 0: Normal operation |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RST_CAL_CLK | 1: Resets the 25 MHz reference clock domain. 0: Normal operation |
| 0x01 | | 0x00 | | | SIG_DET | |
| | 7 | 0 | R | N | SIGDET | Signal detect status. 1: Signal detected at RX inputs. 0: No signal detected at RX inputs. |
| | 6 | 0 | R | N | RESERVED | RESERVED |
| | 5 | 0 | R | N | RESERVED | RESERVED |
| | 4 | 0 | R | N | RESERVED | RESERVED |
| | 3 | 0 | R | N | RESERVED | RESERVED |
| | 2 | 0 | R | N | RESERVED | RESERVED |
| | 1 | 0 | R | N | RESERVED | RESERVED |
| | 0 | 0 | R | N | RESERVED | RESERVED |
| 0x02 | | 0x00 | | | | |
| | 7 | 0 | R | N | RESERVED | RESERVED |
| | 6 | 0 | R | N | RESERVED | RESERVED |
| | 5 | 0 | R | N | RESERVED | RESERVED |
| | 4 | 0 | R | N | RESERVED | RESERVED |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RESERVED | RESERVED |
| 0x03 | | 0x80 | | | CTLE_BOOST | |
| | 7 | 1 | RW | Y | EQ_BW[1] | EQ stage one buffer current (strength) control. Impacts EQ bandwidth. 2'b11 yields highest bandwidth, 2'b00 yields lowest bandwidth. Refer to the Programming Guide for more information. |
| | 6 | 0 | RW | Y | EQ_BW[0] | |
| | 5 | 0 | RW | Y | EQ_BST2[2] | |
| | 4 | 0 | RW | Y | EQ_BST2[1] | |
| | 3 | 0 | RW | Y | EQ_BST2[0] | EQ boost stage 2 controls. Directly goes to analog. No override bit is needed. Refer to the Programming Guide for more information. |
| | 2 | 0 | RW | Y | EQ_BST1[2] | |
| | 1 | 0 | RW | Y | EQ_BST1[1] | |
| | 0 | 0 | RW | Y | EQ_BST1[0] | |
| 0x04 | | 0x90 | | | | |
| | 7 | 1 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | EQ_PD_SD | 1: Power down signal detect 0: Normal operation |

表 4. Channel Register Map (接下页)

| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|-------------|-----|---------------|------|--------|-----------------------|---|
| | 5 | 0 | RW | Y | EQ_HIGH_GAIN | 1: Enable EQ high gain 0: Enable EQ low gain |
| | 4 | 1 | RW | Y | EQ_EN_DC_OFF | RESERVED |
| | 3 | 0 | RW | Y | EQ_PD_EQ | 1: Power down EQ 0: Enable EQ |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | Y | BG_SEL_IPP100[2] | CTLE bias programming. BG_SEL_IPP100[1:0] is in Reg_0x0F[5:4]. |
| | 0 | 0 | RW | Y | EQ_EN_BYPASS | 1: Enable EQ bypass 0: Normal operation, signal travels through EQ. |
| 0x05 | | 0x04 | | | SIG_DET_CONFIG | |
| | 7 | 0 | RW | Y | EQ_SD_PRESET | 1: Force signal detect result to 1 0: Normal operation This bit should not be set if 0x05[6] is also set. |
| | 6 | 0 | RW | Y | EQ_SD_RESET | 1: Force signal detect result to 0 0: Normal operation This bit should not be set if 0x05[7] is also set. |
| | 5 | 0 | RW | Y | EQ_REFA_SEL[1] | Signal detect assert thresholds. Refer to the Programming Guide for more information. |
| | 4 | 0 | RW | Y | EQ_REFA_SEL[0] | |
| | 3 | 0 | RW | Y | EQ_REFD_SEL[1] | Signal detect de-assert thresholds. Refer to the Programming Guide for more information. |
| | 2 | 1 | RW | Y | EQ_REFD_SEL[0] | |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RESERVED | RESERVED |
| 0x06 | | 0xC0 | | | GPIO2 Config | |
| | 7 | 1 | RW | Y | DRV_SEL_VOD[1] | Driver VOD adjust (DC gain), applicable to both linear and FIR limiting mode. Refer to the Programming Guide for more information. |
| | 6 | 1 | RW | Y | DRV_SEL_VOD[0] | |
| | 5 | 0 | RW | Y | DRV_EQ_PD_OV | 1: Driver and equalizer power down manually with Reg_0x06[3] and Reg_0x04[3], respectively. 0: Driver and equalizer are powered down/up by default when LOS=1/0. |
| | 4 | 0 | RW | Y | DRV_SEL_MUTE_OV | Driver mute override: 1: Use register 0x06[1] for mute control. 0: Normal operation. Mute is automatically controlled by signal detect. |
| | 3 | 0 | RW | Y | DRV_PD | 1: Power down the driver. 0: Normal operation, driver power on or off is controlled by signal detect. |
| | 2 | 0 | RW | Y | DRV_PD_CM_LOOP | 1: Disable the driver's common mode loop control circuit. 0: Normal operation, common mode loop enabled. |
| | 1 | 0 | RW | Y | DRV_SEL_MUTE | 1: Mute driver if override bit is enabled. 0: Normal operation |
| | 0 | 0 | RW | Y | DRV_SEL_FIR | Linear versus Limiting Mode select. Refer to the Programming Guide for more information. 1: Enable Limiting FIR mode. 0: Enable Linear mode (disable limiting FIR). |
| 0x07 | | 0x20 | | | | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 1 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RESERVED | RESERVED |
| 0x08 | | 0x54 | | | | |
| | 7 | 0 | RW | Y | RESERVED | RESERVED |

表 4. Channel Register Map (接下页)

| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|-------------|-----|---------------|------|--------|----------------|--|
| | 6 | 1 | RW | Y | RESERVED | RESERVED |
| | 5 | 0 | RW | Y | RESERVED | RESERVED |
| | 4 | 1 | RW | Y | RESERVED | RESERVED |
| | 3 | 0 | RW | Y | BG_SEL_IPTAT25 | 1: Increases the current to the CTLE by 5%. 0: Default |
| | 2 | 1 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RESERVED | RESERVED |
| 0x09 | | 0x00 | | | | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RESERVED | RESERVED |
| 0x0A | | 0x30 | | | | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | Y | RESERVED | RESERVED |
| | 5 | 1 | RW | Y | SD_REF_HIGH | Signal detect threshold controls: 11: Normal operation 10: Signal detect assert or de-assert thresholds reduced. 01: Signal detect assert or de-assert thresholds reduced. 00: Signal detect assert or de-assert thresholds reduced. |
| | 4 | 1 | RW | Y | SD_GAIN | |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RESERVED | RESERVED |
| 0x0B | | 0x1A | | | | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | Y | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 1 | RW | Y | FIR_MAIN[4] | FIR Limiting mode main-cursor control. Refer to the Programming Guide for more information. |
| | 3 | 1 | RW | Y | FIR_MAIN[3] | |
| | 2 | 0 | RW | Y | FIR_MAIN[2] | |
| | 1 | 1 | RW | Y | FIR_MAIN[1] | |
| | 0 | 0 | RW | Y | FIR_MAIN[0] | |
| 0x0C | | 0x40 | | | | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 1 | RW | Y | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | Y | FIR_PST[3] | FIR Limiting mode post-cursor control. There is no sign bit for the post-cursor. The post-cursor always provides a high-pass filter effect. Refer to the Programming Guide for more information. |
| | 2 | 0 | RW | Y | FIR_PST[2] | |
| | 1 | 0 | RW | Y | FIR_PST[1] | |
| | 0 | 0 | RW | Y | FIR_PST[0] | |
| 0x0D | | 0x40 | | | | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 1 | RW | Y | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |

表 4. Channel Register Map (接下页)

| Addr [HEX] | Bit | Default [HEX] | Mode | EEPROM | Field | Description |
|-------------|-----|---------------|------|--------|---------------------|--|
| | 3 | 0 | RW | Y | FIR_PRE[3] | FIR Limiting mode pre-cursor control. There is no sign bit for the pre-cursor. The pre-cursor always provides a high-pass filter effect. Refer to the Programming Guide for more information. |
| | 2 | 0 | RW | Y | FIR_PRE[2] | |
| | 1 | 0 | RW | Y | FIR_PRE[1] | |
| | 0 | 0 | RW | Y | FIR_PRE[0] | |
| 0x0E | | 0x00 | | | | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 0 | RW | N | RESERVED | RESERVED |
| | 4 | 0 | RW | N | RESERVED | RESERVED |
| | 3 | 0 | RW | N | RESERVED | RESERVED |
| | 2 | 0 | RW | N | RESERVED | RESERVED |
| | 1 | 0 | RW | N | RESERVED | RESERVED |
| | 0 | 0 | RW | N | RESERVED | RESERVED |
| 0x0F | | 0x00 | | | | |
| | 7 | 0 | RW | N | RESERVED | RESERVED |
| | 6 | 0 | RW | N | RESERVED | RESERVED |
| | 5 | 0 | RW | Y | BG_SEL_IPP100[1] | CTLE bias programming. BG_SEL_IPP100[2] is in Reg_0x04[1]. 000: 0% additional current (Default) 001: 5% additional current 010: 10% additional current 011: 15% additional current 100: 20% additional current 101: 25% additional current 110: 30% additional current 111: 35% additional current |
| | 4 | 0 | RW | Y | BG_SEL_IPP100[0] | |
| | 3 | 0 | RW | Y | BG_SEL_IPH200_v1[1] | Program pre-driver bias current: 00: 0% additional current (Default) 01: 12.5% additional current 10: 25% additional current 11: 37.5% additional current |
| | 2 | 0 | RW | Y | BG_SEL_IPH200_v1[0] | |
| | 1 | 0 | RW | Y | BG_SEL_IPH200_v0[1] | Program driver bias current: 00: 0% additional current (Default) 01: 12.5% additional current 10: 25% additional current 11: 37.5% additional current |
| | 0 | 0 | RW | Y | BG_SEL_IPH200_v0[0] | |

8 Application and Implementation

注

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The DS280BR810 is a high-speed linear repeater which extends the reach of differential channels impaired by loss from transmission media like PCBs and cables. It can be deployed in a variety of different systems. The following sections outline typical applications and their associated design considerations.

8.2 Typical Application

The DS280BR810 is typically used in three main application scenarios:

1. Backplane and mid-plane reach extension
2. Front-port eye opening for copper and optical applications

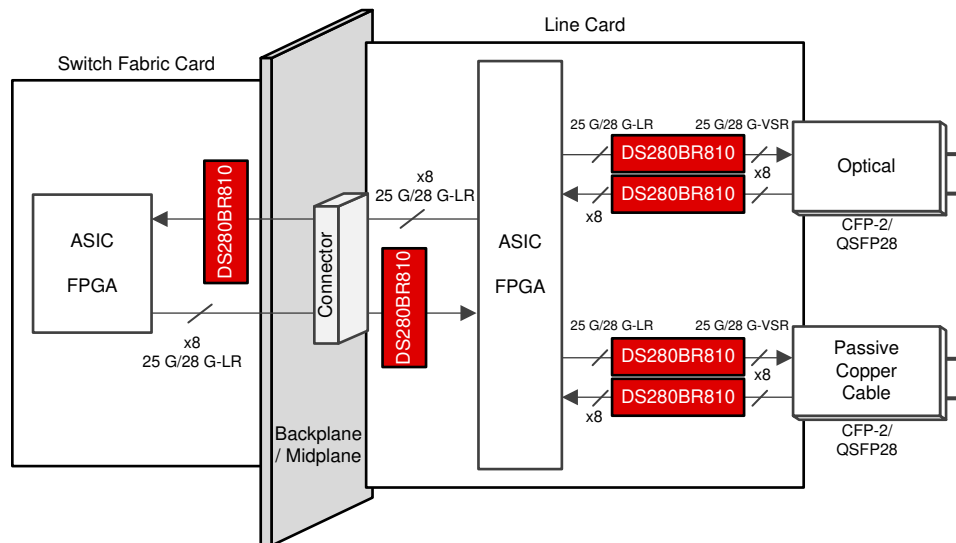


图 6. Typical Application Diagram

8.2.1 Backplane and Mid-Plane Reach Extension

The DS280BR810 has strong equalization capabilities that allow it to equalize insertion loss and extend the reach of backplane channels by 15-20 dB beyond the normal capabilities of the ASICs operating over the channel. The DS280BR810 is designed to apply gain in a linear fashion. In most cases, the DS280BR810 should be placed with the higher loss channel segment at the input and the lower loss channel segment at the output (as shown in 图 7); however, since the DS280BR810 operates in a linear fashion, it can also be used in applications where the lower loss channel segment is at the input and the higher loss channel segment is at the output (as shown in 图 7).

Typical Application (接下页)

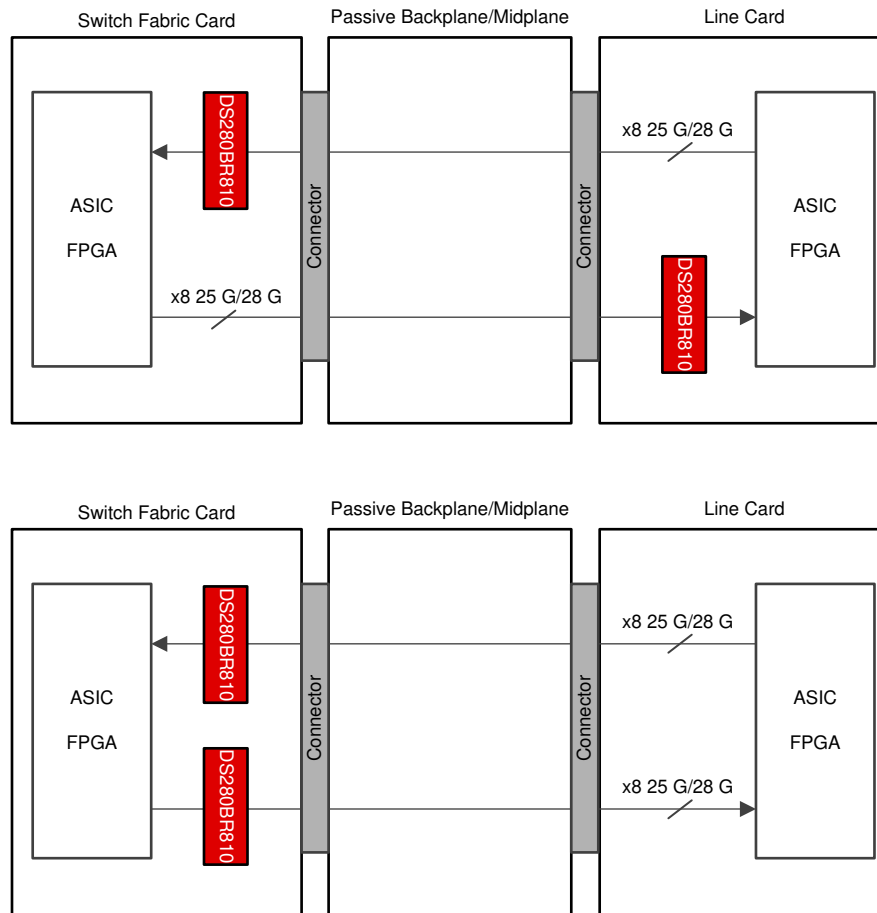


图 7. Typical Backplane and Mid-Plane Application Diagram

Typical Application (接下页)

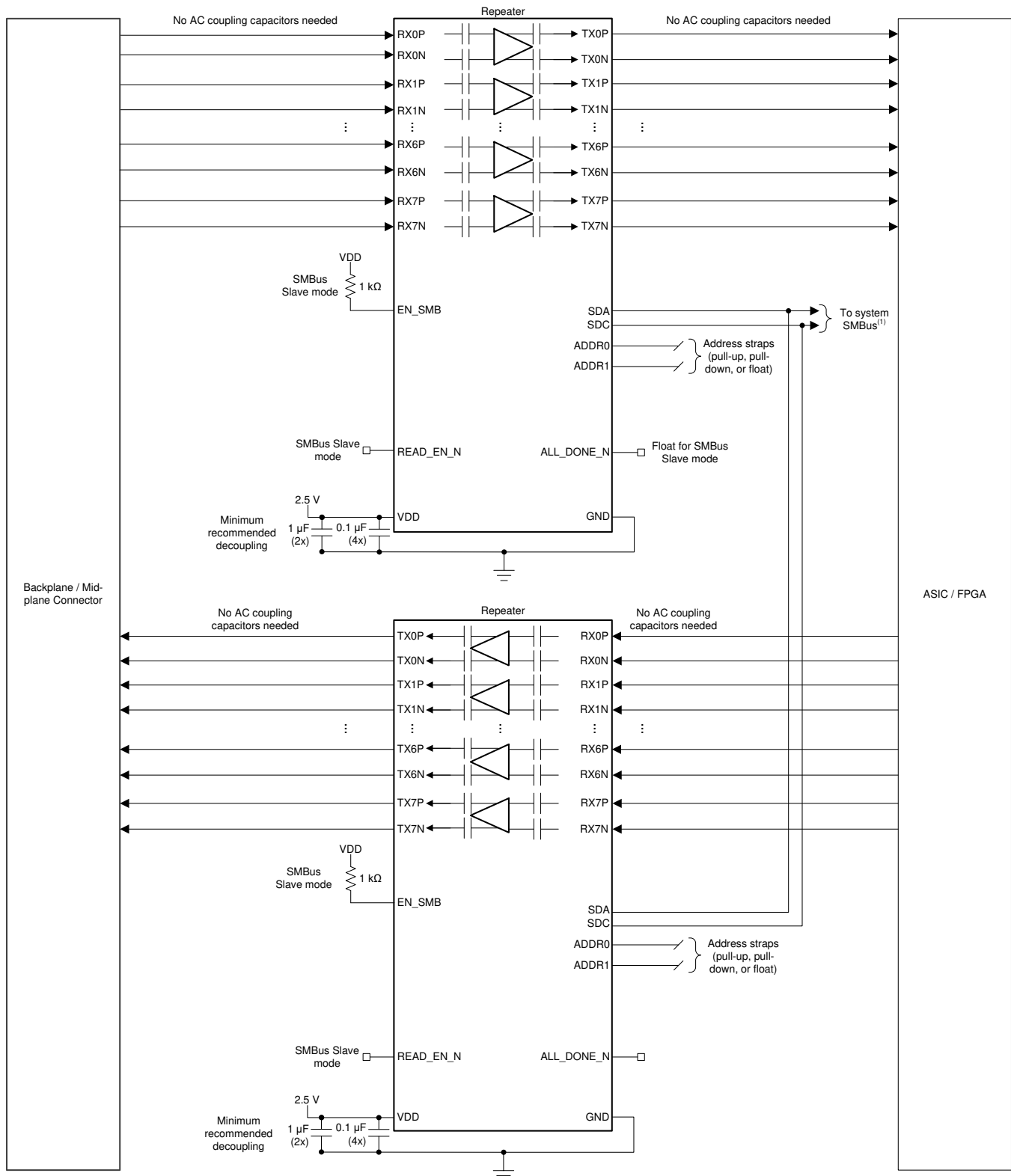


图 8. Typical Backplane and Mid-Plane Schematic

Typical Application (接下页)

8.2.1.1 Design Requirements

For backplane and mid-plane reach extension application, use the guidelines in the table below.

| DESIGN PARAMETER | REQUIREMENT |
|---|--|
| AC Coupling Capacitors | Not required. 220 nF AC coupling capacitors are included in the device package on both the RX and TX side. |
| Input Channel Insertion Loss | ≥ 10 dB at 14 GHz as a rough guideline. For best performance, the input channel insertion loss should be greater than or equal to the equalizer boost setting used in the DS280BR810. |
| Output Channel Insertion Loss | Depends on downstream ASIC and FPGA SerDes capabilities. Should be ≥ 5 dB at 14 GHz as a rough guideline. |
| Total (Input + Output) Channel Insertion Loss | Depends on downstream ASIC and FPGA SerDes capabilities. The DS280BR810 can extend the reach between two ASICs by 15 to 20 dB beyond the ASICs' normal capabilities. |
| Link Partner TX Launch Amplitude | 800 mV _{PP} to 1200 mV _{PP} differential |
| Link Partner TX FIR Filter | Depends on the channel loss. |

8.2.1.2 Detailed Design Procedure

The design procedure for backplane and mid-plane applications is as follows:

1. Determine the total number of channels on the board which require a DS280BR810 for signal conditioning. This will dictate the total number of DS280BR810 devices required for the board. It is generally recommended that channels with similar total insertion loss on the board be grouped together in the same DS280BR810 device. This will simplify the device settings, as similar loss channels generally utilize similar settings.
2. Determine the maximum current draw required for all DS280BR810 devices. This may impact the selection of the regulator for the 2.5 V supply rail. To calculate the maximum current draw, multiply the maximum power supply current by the total number of DS280BR810 devices.
3. Determine the SMBus address scheme needed to uniquely address each DS280BR810 device on the board, depending on the total number of devices identified in step 1. Each DS280BR810 can be strapped with one of 16 unique SMBus addresses. If there are more DS280BR810 devices on the board than the number of unique SMBus addresses which can be assigned, then use an I²C expander like the TCA/PCA family of I²C/SMBus switches and multiplexers to split the SMBus into multiple busses.
4. Determine if the device will be configured from EEPROM (SMBus master mode) or from the system SMBus (SMBus slave mode).
 - a. If SMBus master mode will be used, provisions should be made for an EEPROM on the board with 8-bit SMBus address 0xA0.
 - b. If SMBus slave mode will be used for all device configurations, an EEPROM is not needed.
5. Make provisions in the schematic and layout for standard decoupling capacitors between the device VDD supply and GND. Refer to [Power Supply Recommendations](#) for more information.
6. If there is a need to potentially upgrade to a pin-compatible TI Retimer device, then make provisions in the schematic and layout for a 25 MHz (± 100 ppm) single-ended CMOS clock. Each DS280BR810 buffers the clock on the CAL_CLK_IN pin and presents the buffered clock on the CAL_CLK_OUT pin. This allows multiple (up to 20) DS280BR810 calibration clocks to be daisy chained to avoid the need for multiple oscillators on the board. If the oscillator used on the board has a 2.5 V CMOS output, then no AC coupling capacitor or resistor ladder is required at the input to CAL_CLK_IN. No AC coupling or resistor ladder is needed between one DS280BR810 CAL_CLK_OUT output and the next DS280BR810's CAL_CLK_IN input. The final DS280BR810's CAL_CLK_OUT output can be left floating. A 25 MHz clock is not required for the DS280BR810, but it is good practice to provision for it in case there is a future plan to upgrade to a pin-compatible TI Retimer device.

7. If there is a need to potentially upgrade to a pin-compatible TI Retimer device, then connect the INT_N pin to an FPGA or CPU for interrupt monitoring. Note that multiple INT_N outputs can be connected together. The common INT_N net should be pulled high to 2.5 V or 3.3 V. The INT_N pin on the DS280BR810 does not perform the interrupt functionality that the equivalent pin on the pin-compatible Retimer device does; however, it is good practice to provision for this in case there is a future plan to upgrade to a pin-compatible TI Retimer device.

8.2.2 Front-Port Applications

The DS280BR810 has strong equalization capabilities that allow it to equalize insertion loss and extend the reach of front-port channels by 15 dB beyond the normal capabilities of the ASIC while support CAUI-4 and CR4 electrical requirements. The DS280BR810 is designed to apply gain in a linear fashion in order to support longer distances between the switch ASIC and the front-port module. A single DS280BR810 can be used to support all eight *egress* channels or all eight *ingress* channels for two 100 GbE ports. 图 9 illustrates this configuration.

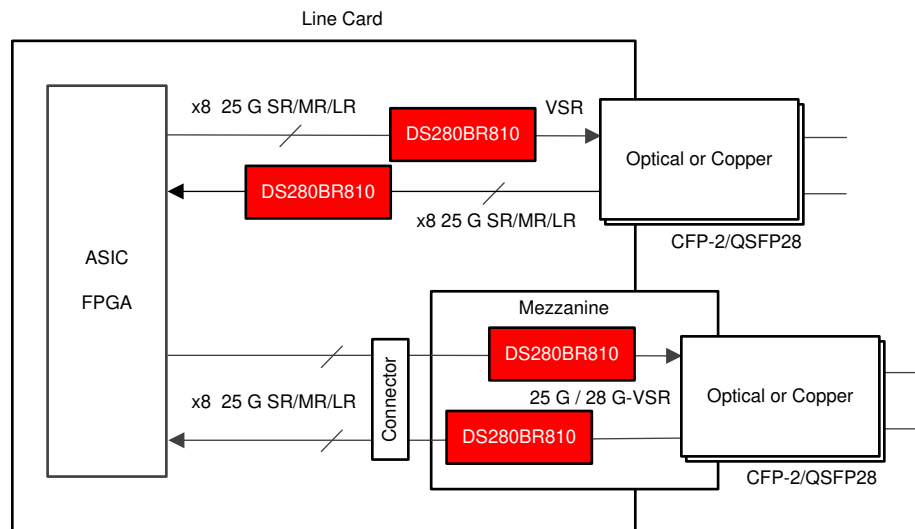


图 9. Typical Front-Port Application Diagram

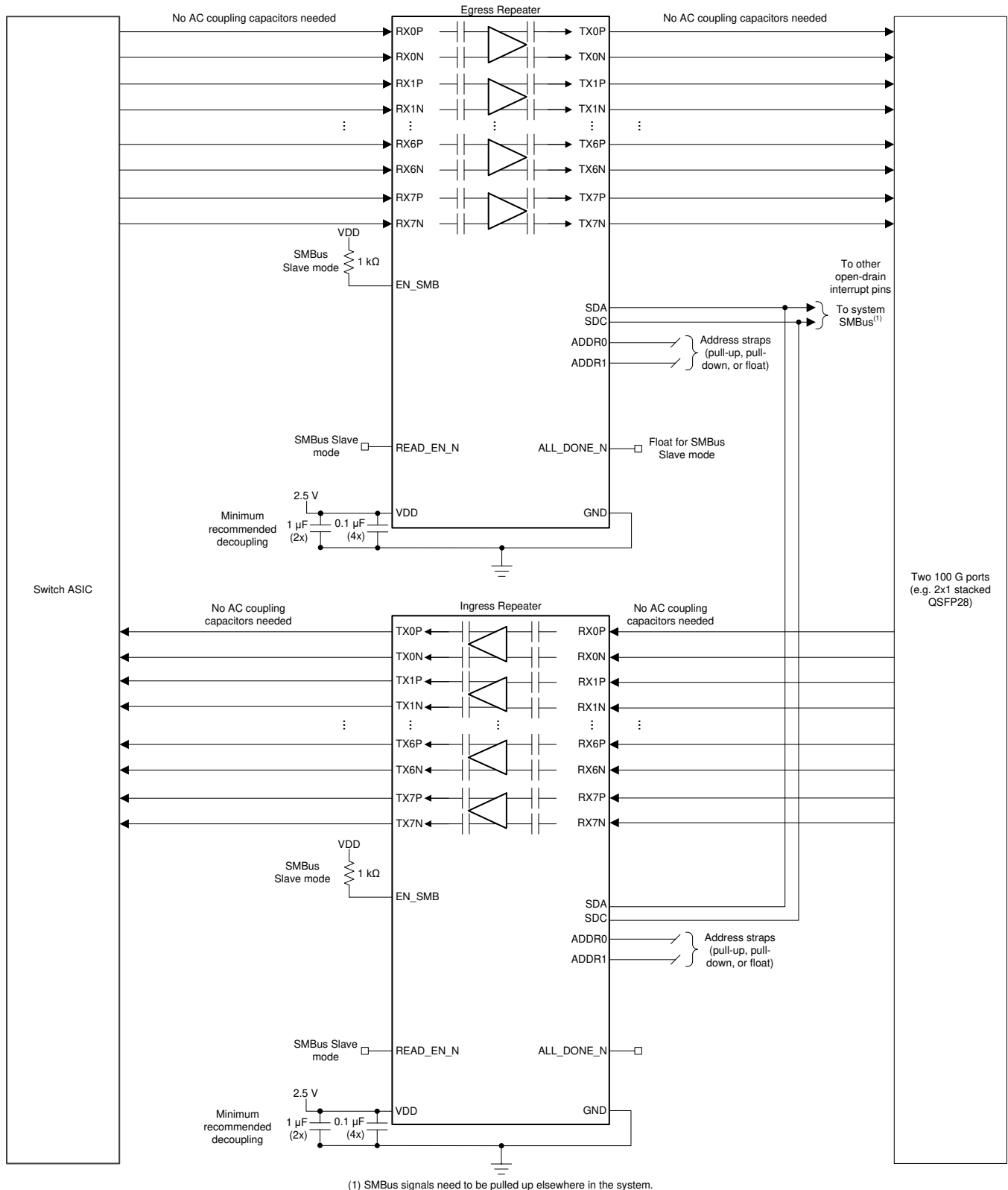


图 10. Typical Front-port Schematic

8.2.2.1 Design Requirements

This section lists some critical areas for high speed printed circuit board design consideration and study.

| DESIGN PARAMETER | REQUIREMENT |
|---------------------------------|---|
| AC Coupling Capacitors | Not required. 220 nF AC coupling capacitors are included in the device package on both the RX and TX side. |
| Input Channel Insertion Loss | ≥ 10 dB at 14 GHz as a <i>rough</i> guideline. For best performance, the input channel insertion loss should be greater than or equal to the equalizer boost setting used in the Repeater. |
| Output Channel Insertion Loss | For best performance in <i>egress</i> applications, place the Repeater close to the front-port cage. For best performance in <i>ingress</i> applications, place the Repeater with ≥ 5 dB loss at 14 GHz between the output and the downstream ASIC. |
| Switch ASIC TX Launch Amplitude | 600 mVppd to 1000 mVppd |

8.2.2.2 Detailed Design Procedure

The design procedure for front-port applications is as follows:

1. Determine the total number of channels on the board which require a DS280BR810 for signal conditioning. This will dictate the total number of DS280BR810 devices required for the board. It is generally recommended that channels belonging to the same QSFP port be grouped together in the same DS280BR810 device. This will simplify the device settings, as similar loss channels generally utilize similar settings.
2. Determine the maximum current draw required for all DS280BR810 devices. This may impact the selection of the regulator for the 2.5 V supply rail. To calculate the maximum current draw, multiply the maximum power supply current by the total number of DS280BR810 devices.
3. Determine the SMBus address scheme needed to uniquely address each DS280BR810 device on the board, depending on the total number of devices identified in step 1. Each DS280BR810 can be strapped with one of 16 unique SMBus addresses. If there are more DS280BR810 devices on the board than the number of unique SMBus addresses which can be assigned, then use an I²C expander like the TCA/PCA family of I²C/SMBus switches and multiplexers to split the SMBus into multiple busses.
4. Determine if the device will be configured from EEPROM (SMBus master mode) or from the system I²C bus (SMBus slave mode).
 1. If SMBus master mode will be used, provisions should be made for an EEPROM on the board with 8-bit SMBus address 0xA0.
 2. If SMBus slave mode will be used for all device configurations, an EEPROM is not needed.
5. Make provisions in the schematic and layout for standard decoupling capacitors between the device VDD supply and GND. Refer to [Power Supply Recommendations](#) for more information.

8.2.3 Application Curves



图 11. Minimal Rx/Tx Channel Test Setup

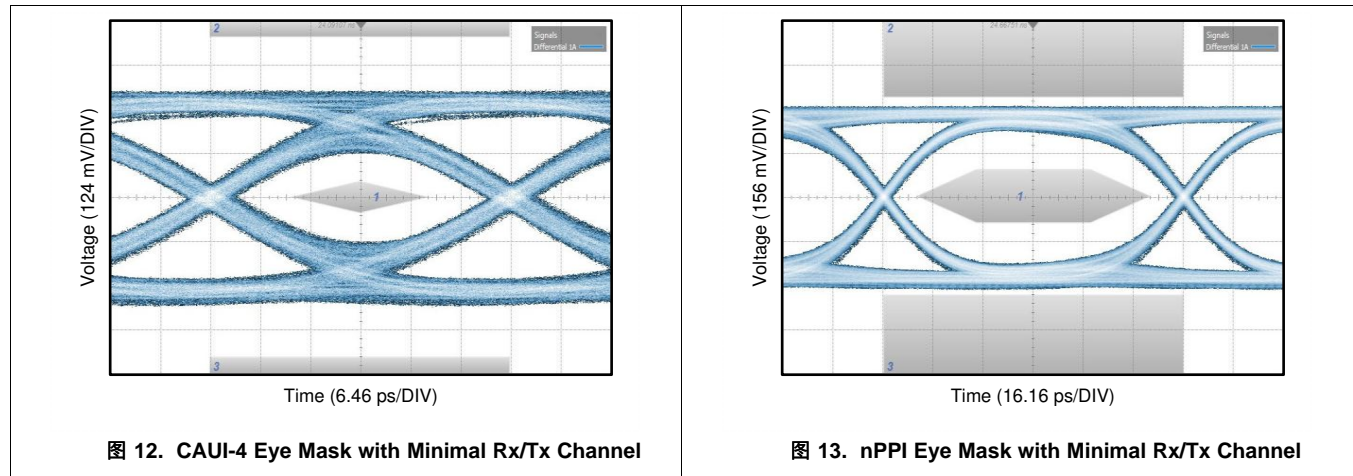


表 5. Settings and Measurements for CAUI-4 and nPPI with Minimal Rx/Tx Channel

| | 25.78125 Gbps (CAUI-4) | 10.3125 Gbps (nPPI) |
|---------------------------------|------------------------|------------------------|
| DS280BR810 Rx Channel Loss | 4 dB @ 12.9 GHz | 2 dB @ 5.2 GHz |
| DS280BR810 Tx Channel Loss | 4 dB @ 12.9 GHz | 2 dB @ 5.2 GHz |
| EQ BST1 | Bypass | Bypass |
| EQ BST2 | 2 | 2 |
| EQ BW | 3 | 3 |
| VOD | 2 | 2 |
| EQ DC Gain Mode | Low | Low |
| Total Jitter @ 1E-15 | 10.4 p _{SP,P} | 10.5 p _{SP,P} |
| Differential Eye Height @ 1E-15 | 233 mV _{P,P} | 445 mV _{P,P} |

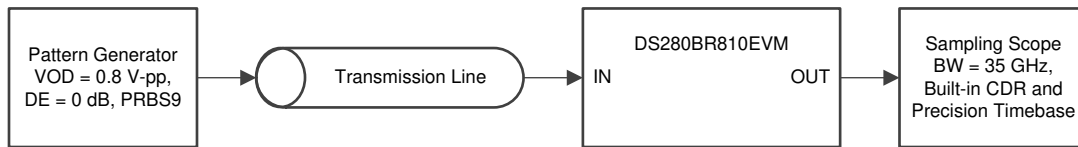


图 14. 5 in Rx and Minimal Tx Channel Test Setup

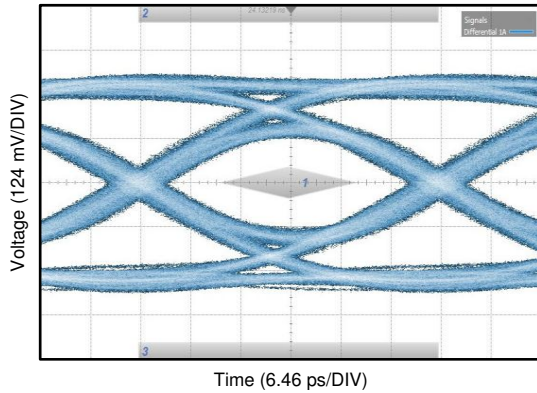


图 15. CAUI-4 Eye Mask with 5 in Rx and Minimal Tx Channel

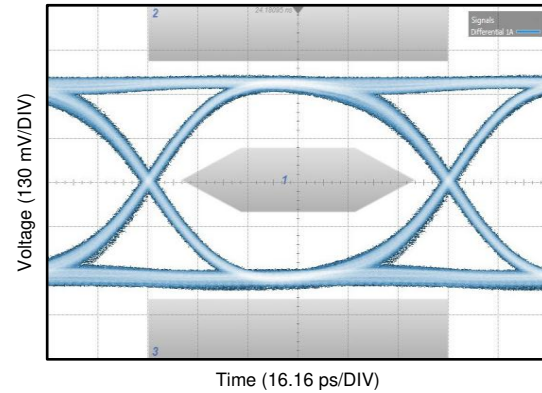
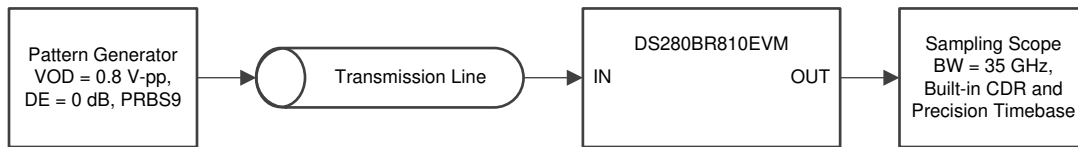
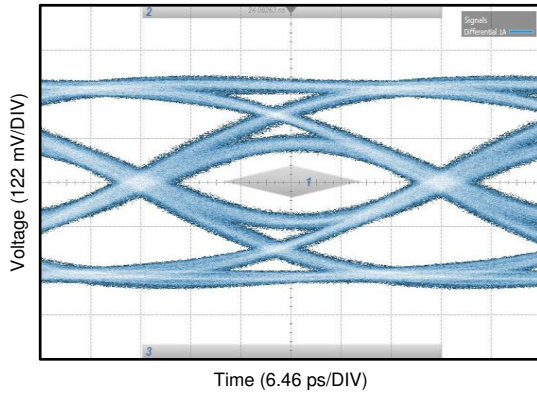
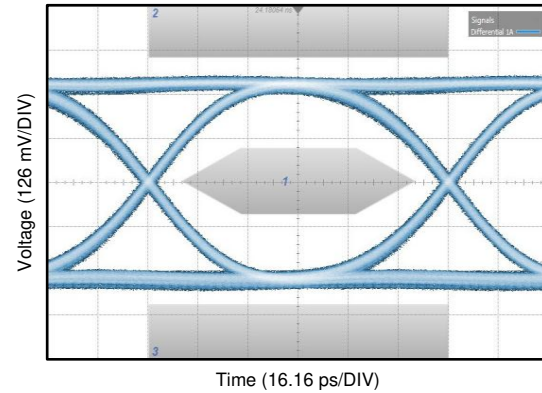


图 16. nPPI Eye Mask with 5 in Rx and Minimal Tx Channel

表 6. Settings and Measurements for CAUI-4 and nPPI with 5 in Rx and Minimal Tx Channel

| | 25.78125 Gbps (CAUI-4) | 10.3125 Gbps (nPPI) |
|---------------------------------|---------------------------------|---------------------------------|
| Transmission Line 1 | 5 in 5 mil FR4 + 8 in SMA cable | 5 in 5 mil FR4 + 8 in SMA cable |
| DS280BR810 Rx Channel Loss | 14 dB @ 12.9 GHz | 6 dB @ 5.2 GHz |
| DS280BR810 Tx Channel Loss | 4 dB @ 12.9 GHz | 2 dB @ 5.2 GHz |
| EQ BST1 | 2 | 2 |
| EQ BST2 | 0 | 0 |
| EQ BW | 3 | 3 |
| VOD | 2 | 2 |
| EQ DC Gain Mode | Low | Low |
| Total Jitter @ 1E-15 | 11.6 ps _{P-P} | 10.4 ps _{P-P} |
| Differential Eye Height @ 1E-15 | 236 mV _{P-P} | 504 mV _{P-P} |


图 17. 10 in Rx and Minimal Tx Channel Test Setup

图 18. CAUI-4 Eye Mask with 10 in Rx and Minimal Tx Channel

图 19. nPPI Eye Mask with 10 in Rx and Minimal Tx Channel
表 7. Settings and Measurements for CAUI-4 and nPPI with 10 in Rx and Minimal Tx Channel

| | 25.78125 Gbps (CAUI-4) | 10.3125 Gbps (nPPI) |
|---------------------------------|----------------------------------|----------------------------------|
| Transmission Line | 10 in 5 mil FR4 + 8 in SMA cable | 10 in 5 mil FR4 + 8 in SMA cable |
| DS280BR810 Rx Channel Loss | 22 dB @ 12.9 GHz | 10 dB @ 5.2 GHz |
| DS280BR810 Tx Channel Loss | 4 dB @ 12.9 GHz | 2 dB @ 5.2 GHz |
| EQ BST1 | 4 | 4 |
| EQ BST2 | 2 | 2 |
| EQ BW | 3 | 3 |
| VOD | 2 | 2 |
| EQ DC Gain Mode | Low | Low |
| Total Jitter @ 1E-15 | 12.4 ps _{P-P} | 10.4 ps _{P-P} |
| Differential Eye Height @ 1E-15 | 148 mV _{P-P} | 504 mV _{P-P} |



图 20. 10 in Rx and 5 in Tx Channel Test Setup

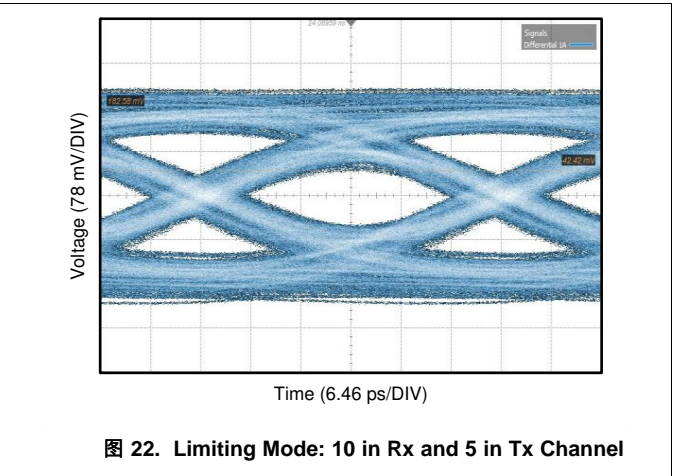
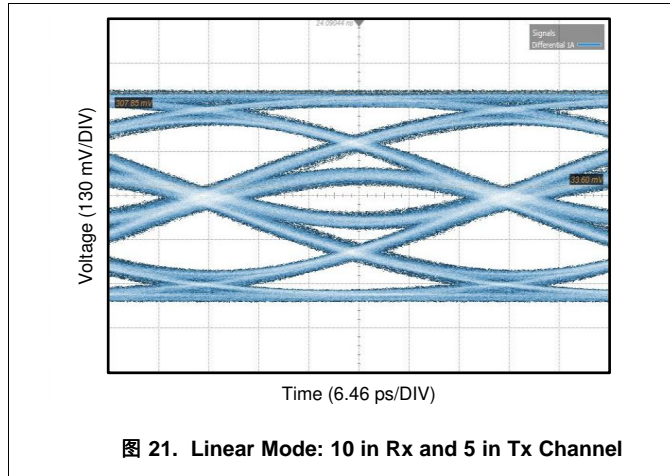


表 8. Settings and Measurements for 10 in Rx and 5 in Tx Channel

| | LINEAR MODE (25.78125 Gbps) | LIMITING MODE (25.78125 Gbps) |
|---------------------------------|--|--|
| Transmission Line 1 | 10 in 5 mil FR4 + 8 in SMA cable | 10 in 5 mil FR4 + 8 in SMA cable |
| Transmission Line 2 | 5 in 5 mil FR4 + 8 in SMA cable | 5 in 5 mil FR4 + 8 in SMA cable |
| DS280BR810 Rx Channel Loss | 22 dB @ 12.9 GHz | 22 dB @ 12.9 GHz |
| DS280BR810 Tx Channel Loss | 14 dB @ 12.9 GHz | 14 dB @ 12.9 GHz |
| Total Channel Loss | 36 dB @ 12.9 GHz | 36 dB @ 12.9 GHz |
| EQ BST1 | 6 | 4 |
| EQ BST2 | 7 | 2 |
| EQ BW | 3 | 3 |
| VOD | 3 | 3 |
| EQ DC Gain Mode | Low | High |
| Tx Main-Cursor | N/A | 16 |
| Tx Pre-Cursor | N/A | -2 |
| Tx Post-Cursor | N/A | -13 |
| Total Jitter @ 1E-15 | 15.8 pSp,p | 18.2 pSp,p |
| Differential Eye Height @ 1E-15 | 61 mVp,p | 79 mVp,p |



图 23. FIR Test Setup

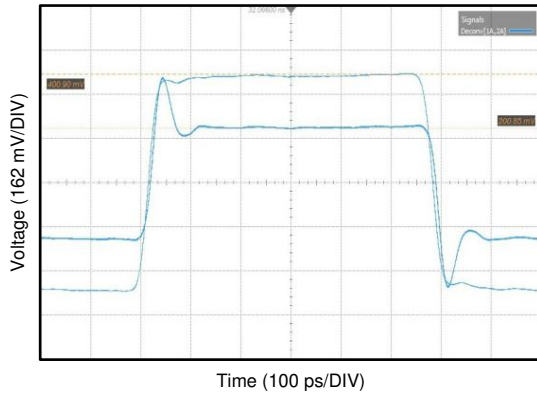


图 24. FIR Post-Cursor Example

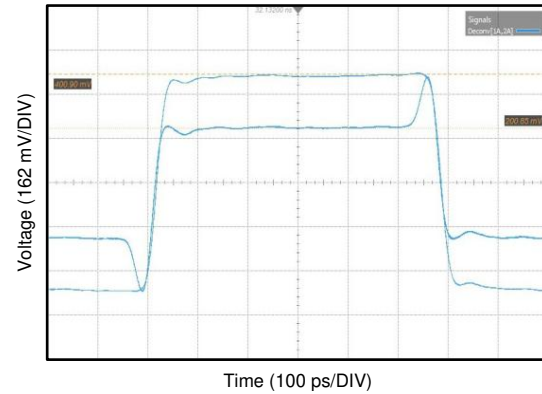


图 25. FIR Pre-Cursor Example

表 9. Example FIR Settings

| 图 24 | 图 25 |
|---------------------------------|---------------------------------|
| (Pre, Main, Post) = (0, 12, 0) | (Pre, Main, Post) = (0, 12, 0) |
| (Pre, Main, Post) = (0, 16, 15) | (Pre, Main, Post) = (11, 12, 0) |

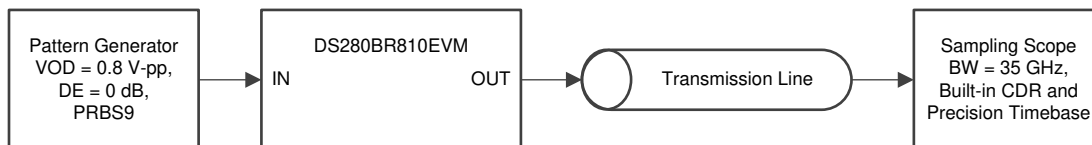


图 26. Transmit FIR Test Setup

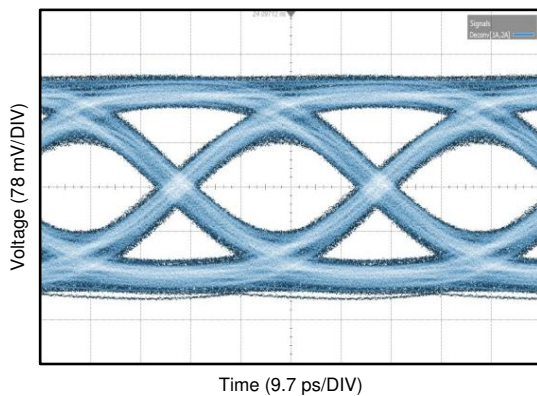


图 27. 25.78125 Gbps Limiting Mode with FIR

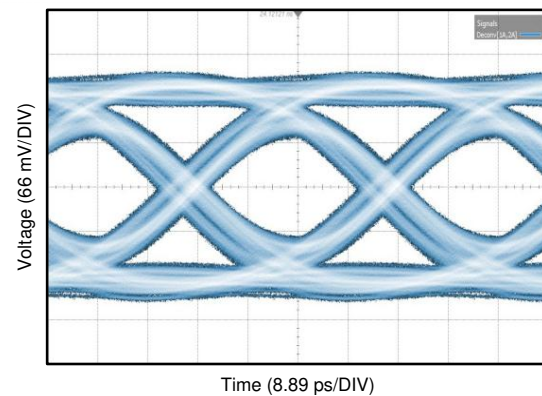


图 28. 28.125 Gbps Limiting Mode with FIR

表 10. Settings and Measurements for 5 in Tx Channel with Limiting Mode

| | 25.78125 Gbps, Limiting Mode | 28.125 Gbps, Limiting Mode |
|---------------------------------|-------------------------------------|-----------------------------------|
| Transmission Line | 5 in 5 mil FR4 + 8 in SMA cable | 5 in 5 mil FR4 + 8 in SMA cable |
| DS280BR810 Tx Channel Loss | 10 dB @ 12.9 GHz | 11 dB @ 14 GHz |
| VOD | 3 | 3 |
| Main-Cursor | 16 | 15 |
| Pre-Cursor | 2 | 2 |
| Post-Cursor | 13 | 14 |
| Total Jitter @ 1E-15 | 13.8 p _{SP,P} | 15.3 p _{SP,P} |
| Differential Eye Height @ 1E-15 | 142 mV _{P,P} | 138 mV _{P,P} |

8.3 Initialization Set Up

The DS280BR810 does not require any particular start-up or initialization sequence. The device defaults to a medium boost value for each channel. It is recommend that the channels be appropriately configured before data traffic is transmitted to the DS280BR810 to avoid issues with the link partner ASIC's adaption. Example configuration settings can be found in the DS280BR810 Programming Guide.

9 Power Supply Recommendations

Follow these general guidelines when designing the power supply:

1. The power supply should be designed to provide the recommended operating conditions outlined in [Specifications](#) in terms of DC voltage, AC noise, and start-up ramp time.
2. The maximum current draw for the DS280BR810 is provided in [Specifications](#). This figure can be used to calculate the maximum current the supply must provide. Typical mission-mode current draw can be inferred from the typical power consumption in [Specifications](#).
3. The DS280BR810 **does not** require any special power supply filtering, such as ferrite beads, provided the recommended operating conditions are met. Only standard supply decoupling is required. Typical supply decoupling consists of a 0.1 μ F capacitor per power pin, and single 1.0 μ F and 10 μ F bulk capacitors.

10 Layout

10.1 Layout Guidelines

The following guidelines should be followed when designing the layout:

1. Decoupling capacitors should be placed as close to the VDD pins as possible. Placing them directly underneath the device is one option if the board design permits.
2. High-speed differential signals should be tightly coupled, skew matched, and impedance controlled.
3. Vias should be avoided when possible on the high-speed differential signals. When vias must be used, care should be taken to minimize the via stub, either by transitioning through most or all layers, or by back drilling.
4. GND relief can be used beneath the high-speed differential signal pads to improve signal integrity by counteracting the pad capacitance.
5. GND vias should be placed directly beneath the device connecting the GND plane attached to the device to the GND planes on other layers. This has the added benefit of improving thermal conductivity from the device to the board.
6. BGA landing pads for a 0.8 mm pitch flip-chip BGA are typically 0.4 mm in diameter (exposed). The actual size of the copper pad will depend on whether solder-mask-defined (SMD) or non-solder-mask-defined solder land pads are used. For more information, refer to TI's Surface Mount Technology (SMT) References website.

10.2 Layout Example

The following example layout demonstrates how all signals can be escaped from the BGA array using stripline routing on a generic 28-layer stackup. This example layout assumes the following:

- Trace width: 0.127 mm (5 mil)

Layout Example (接下页)

- Trace edge-to-edge spacing: 0.152 mm (6 mil)
- VIA finished hole size (diameter): 0.203 mm (8 mil)
- VIA drilled hole size: 0.254 mm (10 mil)
- VIA-to-VIA spacing: 1.0 mm (39 mil), to enhance PCB manufacturability
- No VIA-in-pad used

Note that many other escape routing options exist using different trace width and spacing combinations. The optimum trace width and spacing will depend on the PCB material, PCB routing density, and other factors. Microstrip escape routing is also possible and may be preferable in some application scenarios, including front-port applications.

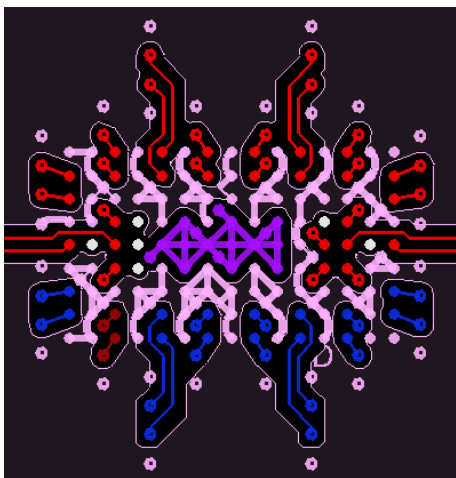


图 29. Top Layer

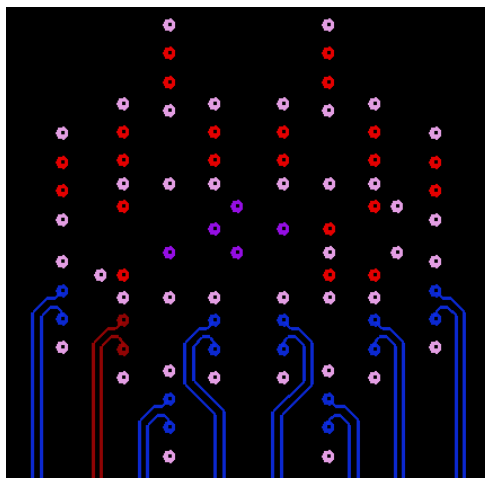


图 30. Internal Signal Layer 1

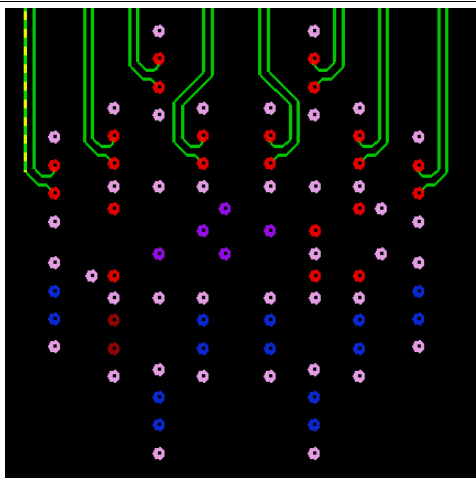


图 31. Internal Signal Layer 2

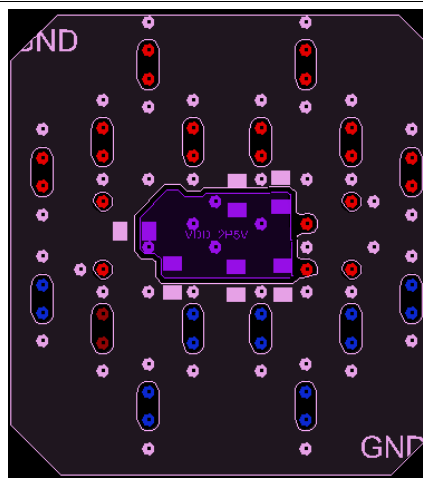


图 32. Bottom Layer

11 器件和文档支持

11.1 文档支持

11.1.1 相关文档

请参阅如下相关文档：

- 德州仪器 (TI), 《了解 25G 和 28G 中继器和重定时器的 *EEPROM* 编程》应用报告
- 德州仪器 (TI), 《TI 25G 和 28G 重定时器和中继器的选择指南》应用报告
- 德州仪器 (TI), 《DS280BR810EVM 用户指南》
- 德州仪器 (TI), 《DS280BR810 编程指南》

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11.5 静电放电警告



这些装置包含有限的内置 ESD 保护。存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

11.6 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。数据如有变更，恕不另行通知，且不会对此文档进行修订。如需获取此数据表的浏览器版本，请查阅左侧的导航栏。

12.1 Package Option Addendum

12.1.1 Packaging Information

| Orderable Device | Status ⁽¹⁾ | Package Type | Package Drawing | Pins | Package Qty | Eco Plan ⁽²⁾ | Lead/Ball Finish | MSL Peak Temp ⁽³⁾ | Op Temp (°C) | Device Marking ⁽⁴⁾⁽⁵⁾ |
|------------------|-----------------------|--------------|-----------------|------|-------------|-------------------------|------------------|------------------------------|--------------|----------------------------------|
| DS280BR810ZBFR | ACTIVE | NFBGA | ZBF | 135 | 1000 | Green (RoHS & no Sb/Br) | SNAGCU | Level-3-260C-168 HR | -40 to 85 | DS280BR8 |
| DS280BR810ZBFT | ACTIVE | NFBGA | ZBF | 135 | 250 | Green (RoHS & no Sb/Br) | SNAGCU | Level-3-260C-168 HR | -40 to 85 | DS280BR8 |

- (1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PRE_PROD Unannounced device, not in production, not available for mass market, nor on the web, samples not available.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.
- (2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check <http://www.ti.com/productcontent> for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)
- (3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device
- (5) Multiple Device markings will be inside parentheses. Only on Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

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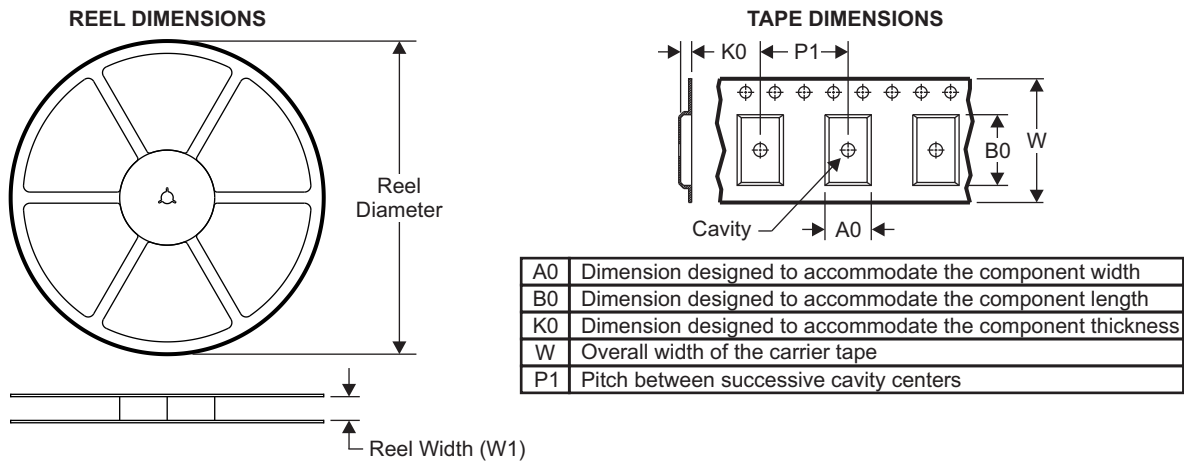
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DS280BR810

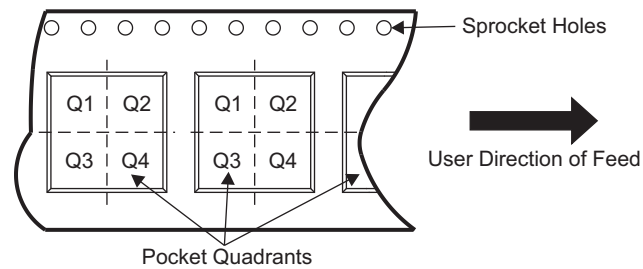
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www.ti.com.cn

12.1.2 Tape and Reel Information

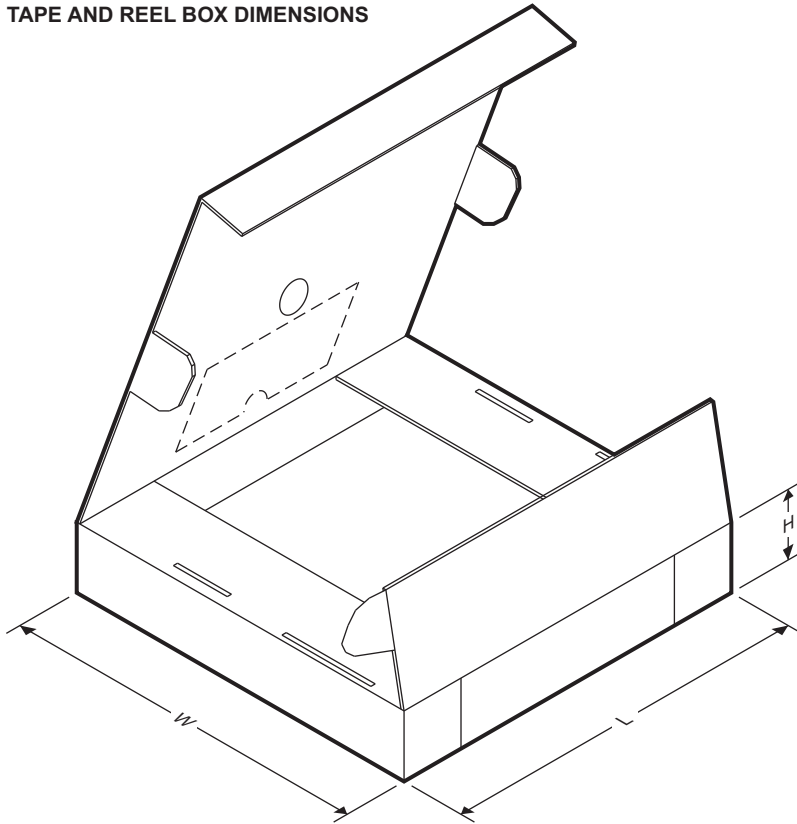


QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| DS280BR810ZBFR | NFBGA | ZBF | 135 | 1000 | 330.0 | 24.4 | 8.4 | 13.4 | 1.9 | 12.0 | 24.0 | Q2 |
| DS280BR810ZBFT | NFBGA | ZBF | 135 | 250 | 178.0 | 24.4 | 8.4 | 13.4 | 1.9 | 12.0 | 24.0 | Q2 |

TAPE AND REEL BOX DIMENSIONS



| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| DS280BR810ZBFR | NFBGA | ZBF | 135 | 1000 | 367.0 | 367.0 | 45.0 |
| DS280BR810ZBFT | NFBGA | ZBF | 135 | 250 | 213.0 | 191.0 | 55.0 |

PACKAGING INFORMATION

| Orderable part number | Status (1) | Material type (2) | Package Pins | Package qty Carrier | RoHS (3) | Lead finish/ Ball material (4) | MSL rating/ Peak reflow (5) | Op temp (°C) | Part marking (6) |
|--------------------------------|---------------|----------------------|-------------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| DS280BR810ZBFR | Active | Production | NFBGA (ZBF) 135 | 1000 LARGE T&R | Yes | SNAGCU | Level-3-260C-168 HR | -40 to 85 | DS280BR8 |
| DS280BR810ZBFR.A | Active | Production | NFBGA (ZBF) 135 | 1000 LARGE T&R | Yes | SNAGCU | Level-3-260C-168 HR | -40 to 85 | DS280BR8 |
| DS280BR810ZBFR.B | Active | Production | NFBGA (ZBF) 135 | 1000 LARGE T&R | - | Call TI | Call TI | -40 to 85 | |
| DS280BR810ZBFT | Active | Production | NFBGA (ZBF) 135 | 250 SMALL T&R | Yes | SNAGCU | Level-3-260C-168 HR | -40 to 85 | DS280BR8 |
| DS280BR810ZBFT.A | Active | Production | NFBGA (ZBF) 135 | 250 SMALL T&R | Yes | SNAGCU | Level-3-260C-168 HR | -40 to 85 | DS280BR8 |
| DS280BR810ZBFT.B | Active | Production | NFBGA (ZBF) 135 | 250 SMALL T&R | - | Call TI | Call TI | -40 to 85 | |

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| DS280BR810ZBFR | NFBGA | ZBF | 135 | 1000 | 330.0 | 24.4 | 8.4 | 13.4 | 1.9 | 12.0 | 24.0 | Q2 |
| DS280BR810ZBFT | NFBGA | ZBF | 135 | 250 | 178.0 | 24.4 | 8.4 | 13.4 | 1.9 | 12.0 | 24.0 | Q2 |

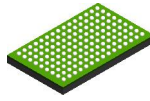
TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| DS280BR810ZBFR | NFBGA | ZBF | 135 | 1000 | 356.0 | 356.0 | 45.0 |
| DS280BR810ZBFT | NFBGA | ZBF | 135 | 250 | 213.0 | 191.0 | 55.0 |

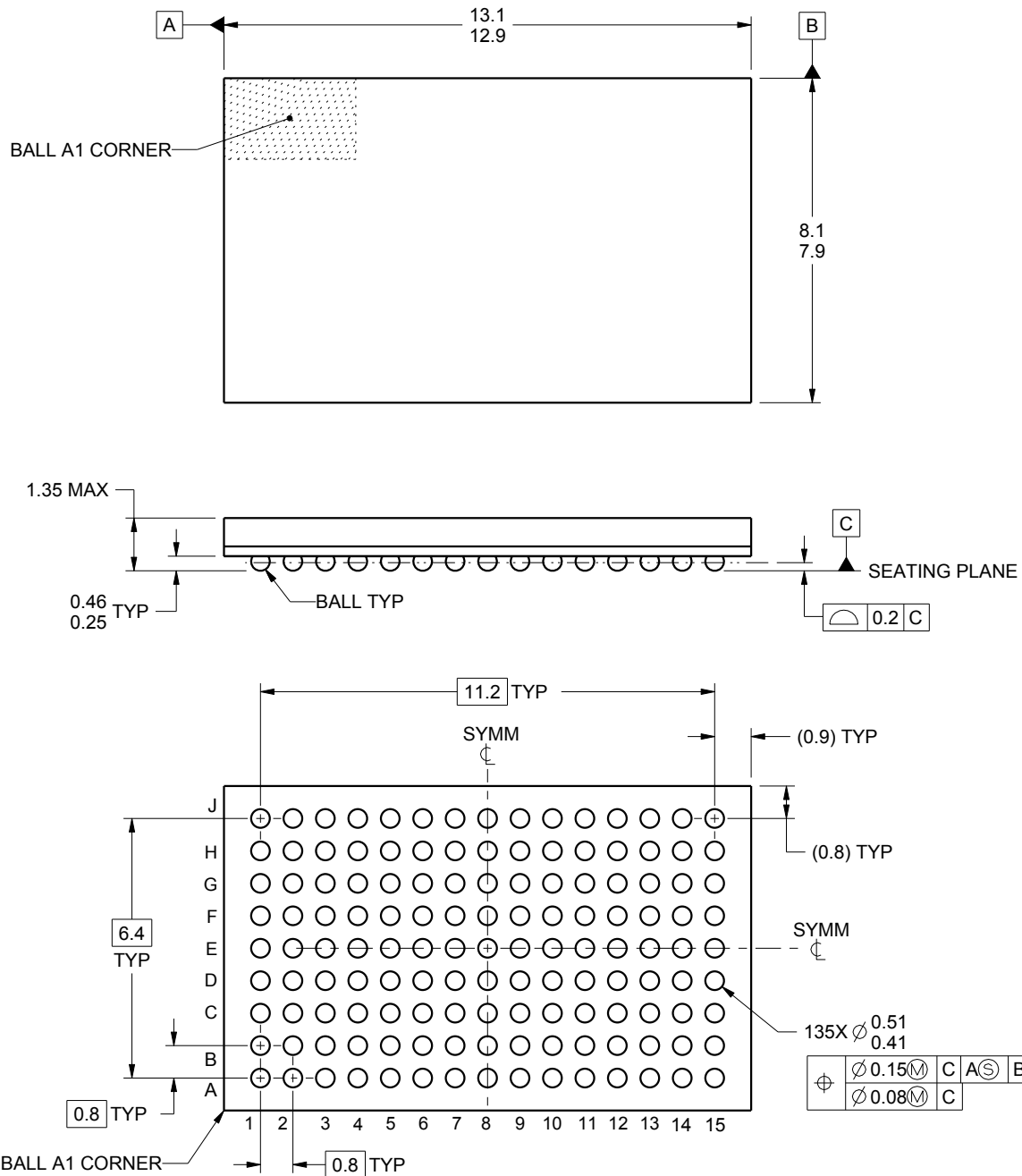
ZBF0135A



PACKAGE OUTLINE

NFBGA - 1.35 mm max height

PLASTIC BALL GRID ARRAY



4221691/A 11/2014

NOTES:

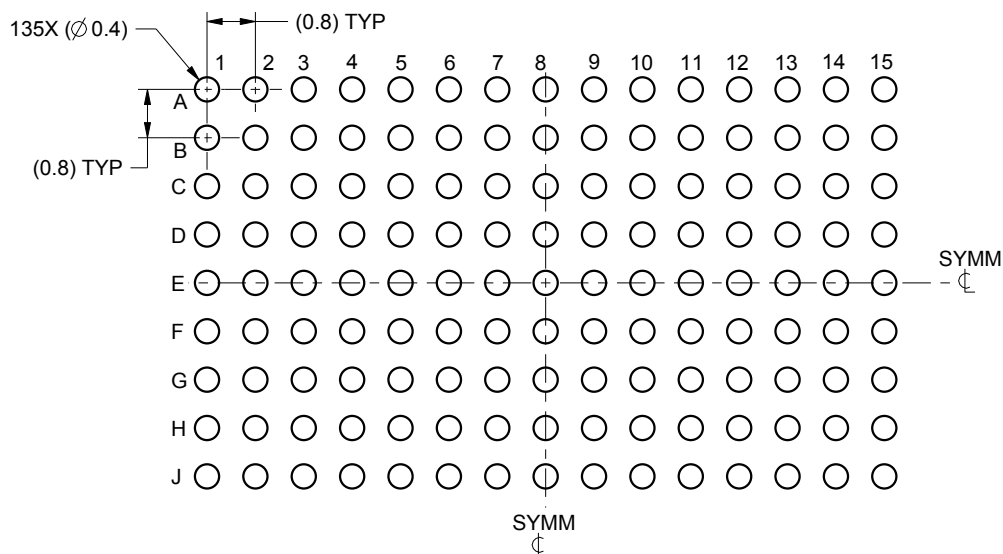
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

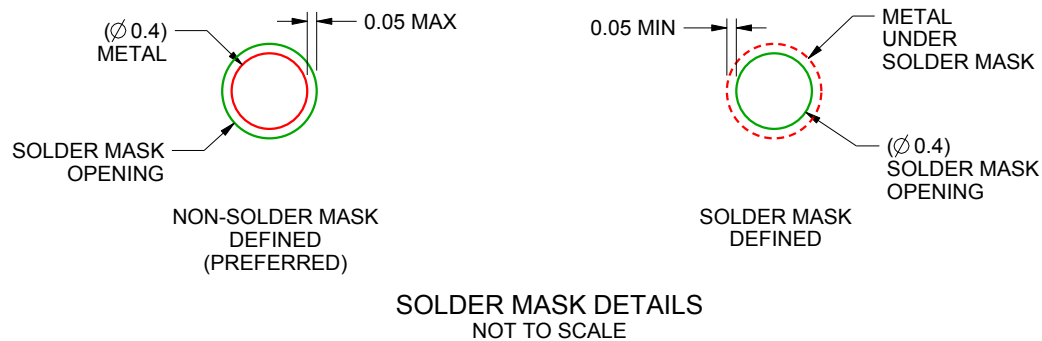
ZBF0135A

NFBGA - 1.35 mm max height

PLASTIC BALL GRID ARRAY



LAND PATTERN EXAMPLE
SCALE:8X



4221691/A 11/2014

NOTES: (continued)

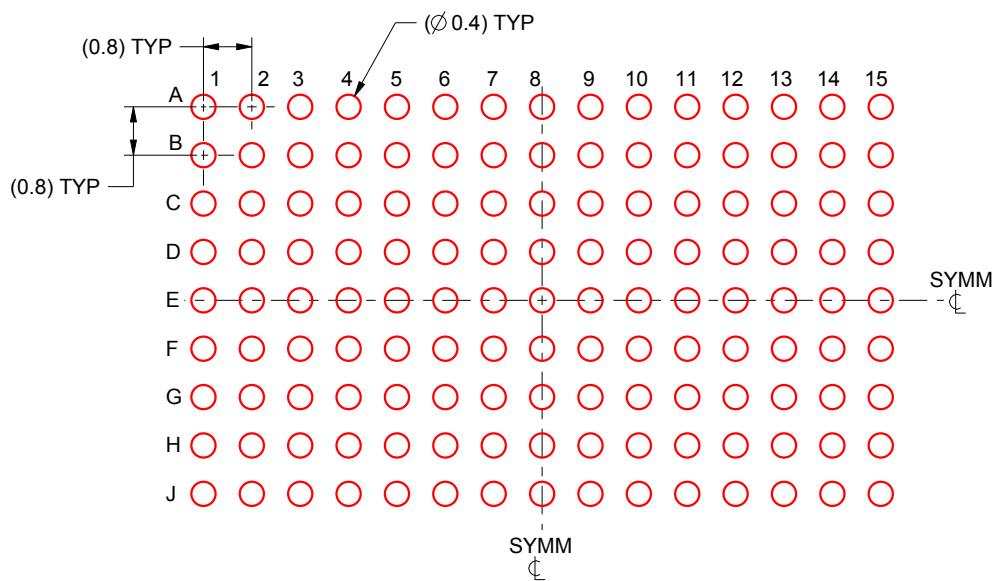
- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For information, see Texas Instruments literature number SPRAA99 (www.ti.com/lit/spraa99).

EXAMPLE STENCIL DESIGN

ZBF0135A

NFBGA - 1.35 mm max height

PLASTIC BALL GRID ARRAY



SOLDER PASTE EXAMPLE
BASED ON 0.15 mm THICK STENCIL
SCALE:8X

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NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

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